

# Influence of inversion on Mg mobility and electrochemistry in spinels

Gopalakrishnan Sai Gautam,<sup>1,2,\*</sup> Pieremanuele Canepa,<sup>2,†</sup>  
Alexander Urban,<sup>2</sup> Shou-Hang Bo,<sup>2</sup> and Gerbrand Ceder<sup>3,2,‡</sup>

<sup>1</sup> Department of Materials Science and Engineering,  
Massachusetts Institute of Technology, Cambridge, MA 02139, USA

<sup>2</sup> Materials Sciences Division, Lawrence Berkeley National Laboratory, Berkeley, CA 94720, USA<sup>†</sup>

<sup>3</sup> Department of Materials Sciences and Engineering,  
University of California Berkeley, CA 94720, USA

Magnesium oxide and sulfide spinels have recently attracted interest as cathode and electrolyte materials for energy-dense Mg batteries, but their observed electrochemical performance depends strongly on synthesis conditions. Using first principles calculations and percolation theory, we explore the extent to which spinel inversion influences Mg<sup>2+</sup> ionic mobility in MgMn<sub>2</sub>O<sub>4</sub> as a prototypical cathode, and MgIn<sub>2</sub>S<sub>4</sub> as a potential solid electrolyte. We find that spinel inversion and the resulting changes of the local cation ordering give rise to both increased and decreased Mg<sup>2+</sup> migration barriers, along specific migration pathways, in the oxide as well as the sulfide.

To quantify the impact of spinel inversion on macroscopic Mg<sup>2+</sup> transport, we determine the percolation thresholds in both MgMn<sub>2</sub>O<sub>4</sub> and MgIn<sub>2</sub>S<sub>4</sub>. Furthermore, we analyze the impact of inversion on the electrochemical properties of the MgMn<sub>2</sub>O<sub>4</sub> cathode via changes in the phase behavior, average Mg insertion voltages and extractable capacities, at varying degrees of inversion. Our results confirm that inversion is a major performance limiting factor of Mg spinels and that synthesis techniques or compositions that stabilize the well-ordered spinel structure are crucial for the success of Mg spinels in multivalent batteries.

## I. INTRODUCTION

Multivalent (MV) batteries, such as those based on Mg<sup>2+</sup>,<sup>1,2</sup> can potentially achieve high volumetric energy density via facile non-dendritic stripping/deposition on an energy-dense metal anode.<sup>3-5</sup> However, the development of viable MV technology is hindered by poor Mg diffusivity in oxide cathodes as well as poor Coulombic efficiencies in liquid electrolytes.<sup>2,5-7</sup>

One pathway to improve Mg migration in solids is to utilize host structures where Mg occupies an unfavorable coordination environment.<sup>8-10</sup> Spinel with composition AM<sub>2</sub>X<sub>4</sub> (A = Mg, M = metal cations, X = O or S) are appealing structures in this regard because of their tetrahedrally-coordinated Mg sites, rather than the preferred octahedral coordination of Mg. Theoretical calculations indeed predict reasonable Mg<sup>2+</sup> migration barriers (~ 550 – 750 meV) in both oxide and sulfide spinels.<sup>11,12</sup> Note that oxide spinels have long been used as cathodes and anodes in commercial Li-ion batteries.<sup>13-19</sup>

Spinel-Mn<sub>2</sub>O<sub>4</sub> is a particularly promising, energy-dense, MV cathode, as it is one of the few oxides<sup>20-25</sup> to have shown electrochemically reversible Mg<sup>2+</sup> intercalation.<sup>26,27</sup> However, the cyclable Mg content, i.e., the observed capacity, seems to depend strongly on the synthesis conditions.<sup>26-28</sup> Several studies on the MgMn<sub>2</sub>O<sub>4</sub> structure<sup>29-33</sup> have indicated that the spinel is prone to *inversion*, i.e., Mg/Mn antisite disorder (see Section II), where the *degree of inversion* can range from 20%<sup>30</sup> to 60%.<sup>29</sup> It has further been argued that the propensity of Mn<sup>3+</sup> to disproportionate into Mn<sup>2+</sup> and Mn<sup>4+</sup> promotes spinel inversion and phase transformations.<sup>16,34</sup> Since inversion directly affects the

local cation arrangement, it may significantly impact the Mg<sup>2+</sup> ionic mobility.<sup>35,36</sup> For the rational design of improved Mg battery cathodes it is, therefore, crucial to understand how inversion in oxide spinels affects Mg<sup>2+</sup> migration.

Inversion is not a phenomenon unique to oxides, and other chalcogenide spinels such as sulfides, which are also important cathode materials in MV technology,<sup>12</sup> are also known to exhibit inversion.<sup>37,38</sup> A recent combined theoretical and experimental study has identified ternary sulfide and selenide spinels as promising Mg-ion conductors with potential applications as solid electrolytes in MV batteries.<sup>38</sup> Solid electrolytes combine the advantage of improved safety with a high Mg transference number. Three promising compounds were reported, namely, MgSc<sub>2</sub>Se<sub>4</sub>, MgSc<sub>2</sub>S<sub>4</sub>, and MgIn<sub>2</sub>S<sub>4</sub>.<sup>38</sup> MgIn<sub>2</sub>S<sub>4</sub> spinel had previously been reported,<sup>39,40</sup> and the available literature as well as our own synthesis attempts (Figure S1 in Supporting Information, SI\*#) indicate that the compound is prone to inversion, where the degree of inversion can be as high as ~ 85% (Table S2 in SI).

In the present work, motivated by the importance of the spinel structure for MV battery technology, we explore the influence of spinel inversion on Mg mobility in ternary oxides and sulfides, using MgMn<sub>2</sub>O<sub>4</sub> and MgIn<sub>2</sub>S<sub>4</sub> as the prototype for each class of spinels. We consider all possible local cation environments that arise due to inversion and compute the activation barriers for Mg migration in each scenario using first-principles calcu-

\*# Electronic Supporting Information available free of charge online at <http://dx.doi.org/10.1021/acs.chemmater.7b02820>

lations. The high requirement for the ionic conductivity in solid electrolytes typically demands migration barriers to be  $< 500$  meV, as observed in solid Li-conductors,<sup>41</sup> while cathodes can operate under lower ionic mobilities (barriers  $\sim 750$  meV, see Section IV A)<sup>2</sup> as the required length is less than for a conductor. Hence, we limit accessible  $\text{Mg}^{2+}$  migration paths to those with a barrier less than 500 meV and 750 meV for operation as a solid electrolyte and cathode, respectively. We will use  $\text{MgMn}_2\text{O}_4$  as the prototype cathode for which we restrict barriers to 750 meV and  $\text{MgIn}_2\text{S}_4$  as an example of an electrolyte (barriers  $< 500$  meV).

Our results indicate that inversion, in both solid electrolytes and cathodes, can simultaneously cause a decrease in activation barriers across certain migration trajectories while increasing the barriers across others, leading to a complex interplay of opening and closing of specific Mg migration pathways. To quantify the impact of these variations in the microscopic activation barriers on macroscopic Mg diffusion, we estimate the critical Mg concentrations (percolation thresholds) required to facilitate  $\text{Mg}^{2+}$  diffusion through the structure at different degrees of inversion. Note that Mg extraction from the cathode material creates Mg-vacancies that can affect the percolation properties. For example, vacancies can cause migration pathways that are inactive in the fully discharged composition to become accessible. Hence, for a cathode, we examine the variation of the percolation threshold with vacancy content in the spinel lattice. In electrolytes, the Mg concentration does not significantly vary and we do not consider the effect of Mg-vacancies in  $\text{MgIn}_2\text{S}_4$ . Our estimates indicate that stoichiometric  $\text{MgMn}_2\text{O}_4$  and  $\text{MgIn}_2\text{S}_4$  spinels remain percolating up to  $\sim 55$ – $59\%$  and  $44\%$  inversion, respectively. Finally, we discuss the impact of spinel inversion on Mg-electrochemistry in the  $\text{Mn}_2\text{O}_4$  cathode by evaluating the 0 K phase diagram, average voltages and the accessible Mg capacity at various degrees of inversion.

While previous studies have analyzed the impact of inversion on structural, thermal, electronic, and magnetic properties,<sup>30,42–45</sup> the effect on Mg mobility in spinels has not yet been investigated. Understanding the influence of inversion on ion mobility will provide guidelines to tune the synthesis and electrochemical conditions of both cathodes and solid electrolytes, not only in MV systems but also in existing Li-ion architectures.<sup>46</sup> Finally, our results emphasize the importance of the topology of cation sites in setting the migration behavior within a general anion framework.<sup>47</sup>

## II. STRUCTURE

A spinel configuration is a specific ordering of cation sites (A and M in  $\text{AM}_2\text{X}_4$ ) in a face-centered cubic (FCC) packing of anion sites (X), as shown in Figure 1. In a “normal” spinel, half of the octahedral (*oct*) sites, i.e.,  $16d$ , are occupied by M atoms (Mn/In, blue octahedra

in Figure 1), while  $1/8$  of the tetrahedral (*tet*) sites ( $8a$ ) are occupied by A (Mg, orange tetrahedra) cations.

Polyhedra in the spinel structure share faces, edges and corners, as summarized in Table I. For example, the  $8a$  sites that are occupied by A are face-sharing with vacant (Vac)  $16c$  *oct* sites (dashed red square in Figure 1a), edge-sharing with vacant  $48f$  *tet* (dashed red triangle) and corner-sharing with vacant *tet* ( $48f, 8b$ ) and M-containing  $16d$  *oct* sites.<sup>48</sup> Face-sharing polyhedra have the lowest cation–cation distance, leading to the highest level of electrostatic repulsion, followed by edge-sharing and subsequently corner-sharing polyhedra.<sup>49</sup> Indeed, the  $16c$ ,  $48f$  and  $8b$  sites are vacant in spinel lattices ( $8b$  not shown in Figure 1) since they face-share with occupied  $8a$  or  $16d$  sites.

Inversion in a spinel structure refers to the collection of anti-site defects in the  $8a$  (A) and  $16d$  (M) sublattices, as shown in Figure 1b. The degree of inversion,  $i$ , is defined as the fraction of  $8a$  sites occupied by M cations, with a value of 0 (or 0%) and 1 (100%) indicating a normal and a fully inverted spinel, respectively. Thus, cations A and M are exchanged in inverted spinels (green arrows in Figure 1b), leading to a stoichiometry of  $\text{A}_{1-i}\text{M}_i[\text{A}_{i/2}\text{M}_{1-(i/2)}]_2\text{X}_4$ , compared to  $\text{AM}_2\text{X}_4$  in normal spinels.

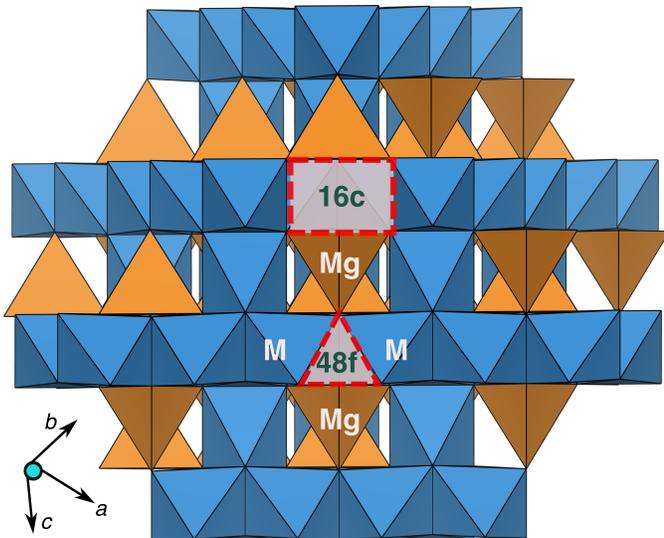
### A. Possible Mg-hops

Figure 2 and Table II summarize the possible local cation arrangements in a spinel structure that can originate from inversion. The orange, blue, and green polyhedra in Figure 2 correspond to Mg, M, and mixed (Mg/M) occupation, respectively, with the arrows in each panel indicating the Mg migration trajectory. The dashed rectangles and triangles signify vacancies. Grey polyhedra correspond to  $8a$  sites that are either cation occupied or vacant. While Figure 2a indicates the migration trajectory in a normal spinel, panels b, c, d, and e depict the possible Mg-hops that can occur in an inverted spinel. The sub-panels in Figure 2b correspond to slices along perpendicular directions, i.e., the  $8a$  sites in the left sub-panel of Figure 2b are perpendicular to the plane of the paper in the right sub-panel.

In a normal spinel, the rate for Mg diffusion is determined by the hop between adjacent  $8a$  *tet* sites face-sharing with a  $16c$  octahedron, as shown in Figure 2a. Hence, the migration topology is *tet* – *oct* – *tet*, and referred to as “Hop 1” in our work. The intermediate  $16c$  site in Hop 1 shares edges with six  $16d$  *oct* sites (“ring” sites) that are occupied by M cations (2 out of 6 ring sites are shown in Figure 2a). It was recently proposed<sup>8,11,12</sup> that the migration barrier in normal spinels, both oxides and sulfides, is predominantly set by the size of the shared triangular face (not shown in Figure 2a) between the  $8a$  *tet* and  $16c$  *oct* sites.

Along the *tet* – *oct* – *tet* migration pathway in inverted spinels (referred to as “Hop 2”) the  $16d$  ring sites can be

a) Normal



b) Inverted

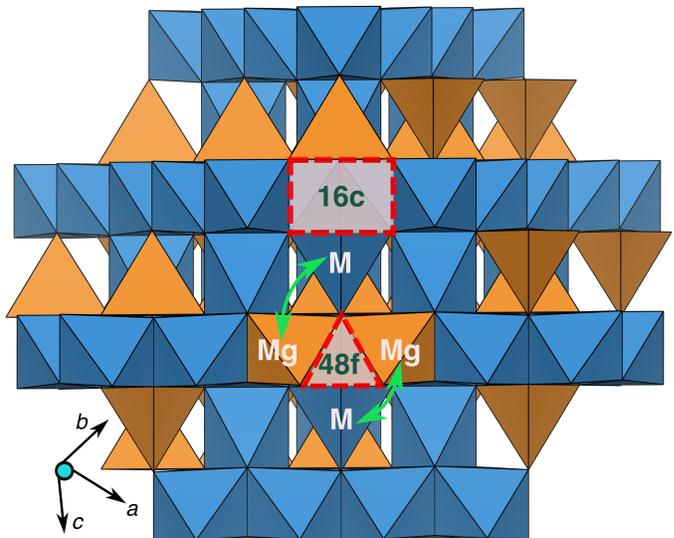


FIG. 1: Schematic of a normal (a) and an inverted (b) spinel  $\text{MgM}_2\text{X}_4$  ( $\text{M} = \text{Mn, In}$  and  $\text{X} = \text{O, S}$ ). The blue and orange polyhedra correspond to the M ( $16d, oct$ ) and Mg ( $8a, tet$ ). The dashed rectangle indicates the vacant  $16c, oct$  site and the dashed triangle the vacant  $48f, tet$  site. In (b), green arrows display the exchange of Mg and M sites, leading to inversion in the spinel.

TABLE I: Notations used in the  $\text{AM}_2\text{X}_4$  structure of Figure 1. Vac indicates vacancy. No. sites is normalized against the conventional (cubic) cell of a normal spinel with 32 anions.

Site	Coordination	Ion in normal spinel	Sharing neighbors			No. sites
			Face	Edge	Corner	
8a	<i>tet</i>	A ( $\text{Mg}^{2+}$ )	16c	48f	48f, 16d, 8b	8
16d	<i>oct</i>	M ( $\text{Mn}^{3+,4+}/\text{In}^{3+}$ )	8b, 48f	16c, 16d	8a, 48f	16
16c	<i>oct</i>	Vac	8a, 48f	16d, 16c	8b, 48f	16
48f	<i>tet</i>	Vac	16d, 16c	8a, 8b, 48f	8a, 8b, 16c, 16d	48
8b	<i>tet</i>	Vac	16d	48f	48f, 16c, 8a	8

occupied by both M and Mg cations, as indicated by the six green polyhedra in the right sub-panel of Figure 2b. To evaluate  $\text{Mg}^{2+}$  migration along Hop 2, we considered multiple configurations from 1 ring site occupied by Mg to all 6 ring sites being occupied by Mg. Since each ring site occupancy (e.g., 2/6 or 3/6 Mg) corresponds to a large number of possible cation decorations on the ring sites, we used the decoration that had the lowest electrostatic energy, as obtained by minimizing the Ewald energy of the unit cell<sup>50</sup> using classical charges in the spinel framework. The specific cation arrangements used to evaluate the Mg migration barriers along Hop 2 are displayed in Figure S13.

As inversion leads to  $\text{Mg}^{2+}$  occupancy of 16d sites, Mg-hopping across 16d sites must also be considered. A 16d – 16d hop can occur through two possible tetrahedral intermediate sites, the 8b and 48f. The 8b sites typically share all their triangular faces with occupied 16d sites and are therefore not open to  $\text{Mg}^{2+}$  migration due to high electrostatic repulsion, as shown by previous

studies.<sup>8,36,47</sup> However, the 48f sites share 2 triangular faces with vacant 16c sites, enabling them to act as viable intermediate sites for  $\text{Mg}^{2+}$  hopping. As such, we only consider the 16d – 16d hop via the 48f as intermediate site, leading to a 16d – 48f – 16d topology (Figures 2c, d, and e). The 48f shares one of its edges with an 8a tet site (Table I), where the “edge-8a” can be occupied by  $\text{Mg}^{2+}$  (“Hop 3”, Figure 2c),  $\text{M}^{3+/4+}$  (“Hop 4”, Figure 2d) or a vacancy (“Hop 5”, Figure 2c). Additionally, across Hops 3, 4, and 5, we consider two scenarios where the 8a sites that share a corner with the 48f (“corner-8a”, grey polyhedra in Figure 2) are either occupied by cations or left vacant.

## B. Percolation theory

While activation barriers for the various cation arrangements in Figure 2 determine the active  $\text{Mg}^{2+}$  migration hops (or channels) on the atomic scale, the macro-

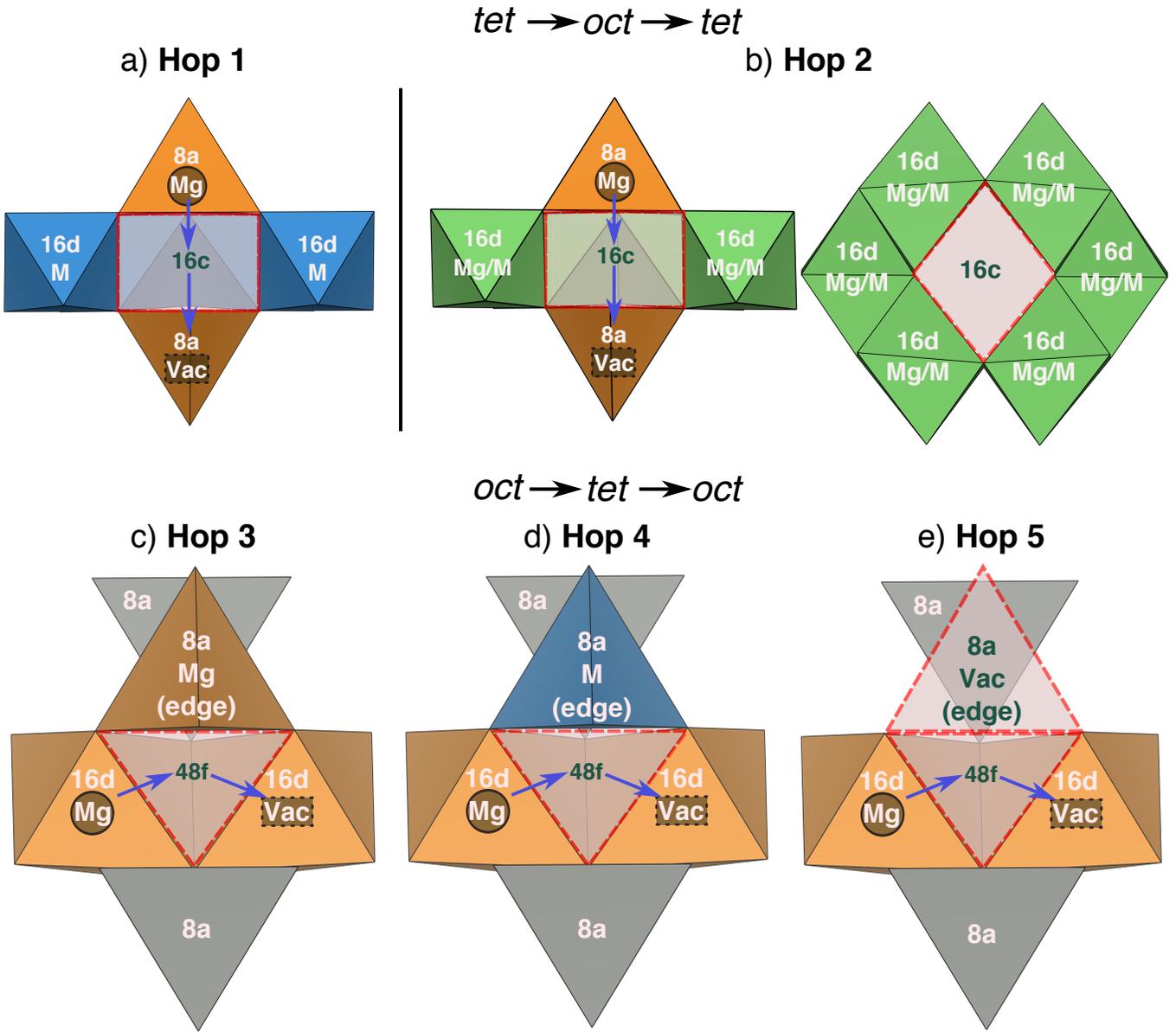


FIG. 2: Local cation environments and various Mg hops considered in an inverted spinel structure. In all migration scenarios a Mg atom migrates from an occupied site (indicated by solid black circles) to an adjacent vacant site (dashed black rectangles), along the trajectory indicated by the arrows. Hops 1 (a) and 2 (b) occur with a  $tet \rightarrow oct \rightarrow tet$  topology, while hops 3 (c), 4 (d), and 5 (e) occur along an  $oct \rightarrow tet \rightarrow oct$  pathway. Blue and orange polyhedra correspond to Mg and M ( $M = Mn, In$ ), while green polyhedra indicate mixed M/Mg occupancy. In the case of Hops 3, 4, and 5 the  $8a$  sites corner-sharing with the intermediate  $48f$  site are shown as grey polyhedra. The notation “edge” in panels (c), (d) and (e) corresponds to the  $8a$  site that edge-shares with the  $48f$ . Vac indicates vacancy.

scopic diffusion of  $Mg^{2+}$ , which is essential for (dis)charge of cathodes or ionic conduction in solid electrolytes, depends on the existence of a percolating network of active migration channels. As the  $8a - 16c - 8a$  channels form a percolating network throughout the spinel structure, stoichiometric normal spinels with Mg in  $8a$  enable macroscopic diffusion of  $Mg^{2+}$  as long as the  $8a - 16c - 8a$  hop is open, i.e., the migration barrier for Hop 1 is below a threshold value. However, inversion leads to mixing of cation occupancies in both the  $8a$  and  $16d$  sites, poten-

tially causing some  $8a - 16c - 8a$  channels to close (due to higher  $Mg^{2+}$  migration barriers along Hop 2) while opening new channels typically closed in a normal spinel (e.g., Hops 3, 4, or 5). Hence, in addition to identifying facile microscopic hops, it is important to consider whether a percolating network of low-barrier migration channels exists. Analogous studies have been done on  $Li^+$  percolation in rocksalt lattices.<sup>36</sup>

In percolation theory, the site percolation problem<sup>51–54</sup> identifies the critical concentration,  $x = x_{crit}$ , at which

TABLE II: Summary of all hops considered for evaluating  $\text{Mg}^{2+}$  mobility in inverted spinels, where  $M = \text{Mn, In}$  and  $\text{Vac} = \text{Vacancy}$ . The neighbor column indicates the site that edge-shares with the intermediate site in the corresponding hop. The last column signifies the (maximum) number of configurations, along each migration trajectory, for which migration barriers have been calculated in this work. For example along Hop 3, the corner- $8a$  sites being cation-occupied and vacant are the two configurations considered.

Hop	Topology	Intermediate site neighbor(s)	# configurations
1	$8a - 16c - 8a$ ( <i>tet - oct - tet</i> )	$16d$ ( <i>oct</i> , M)	1
2	$8a - 16c - 8a$ ( <i>tet - oct - tet</i> )	$16d$ ( <i>oct</i> , Mg/M)	6
3	$16d - 48f - 16d$ ( <i>oct - tet - oct</i> )	$8a$ ( <i>tet</i> , Mg)	2
4	$16d - 48f - 16d$ ( <i>oct - tet - oct</i> )	$8a$ ( <i>tet</i> , M)	2
5	$16d - 48f - 16d$ ( <i>oct - tet - oct</i> )	$8a$ ( <i>tet</i> , Vac)	2

an infinite network of contiguous connected sites exists in an infinite lattice of randomly occupied sites. In terms of ionic diffusion,  $x_{crit}$  sets the “percolation threshold”, above which percolating channels exist in a given structure and macroscopic ion diffusion is feasible. While percolation thresholds are accessible analytically for 2D lattices,<sup>53</sup> Monte-Carlo (MC) simulations need to be used to estimate  $x_{crit}$  in 3D structures.<sup>36,55,56</sup>

The existence of a percolating diffusion network in a structure at a certain  $x$  ( $> x_{crit}$ ) does not imply that all ions in the structure can be (reversibly) extracted. Mg sites that are not part of a percolating network will form isolated clusters throughout the structure so that the amount of extractable ions is lower than the total concentration, i.e.,  $x_{ext} < x$ . The quantity  $x_{ext}$  can be assumed to correspond to the capacity of a cathode material. Numerically,  $x_{ext}$  is also estimated from MC simulations.<sup>36</sup>

In summary, the two central quantities obtained from percolation MC simulations are the Mg concentration beyond which macroscopic diffusion is feasible ( $x_{crit}$ ) and the fraction of extractable Mg ions in a percolating structure ( $x_{ext}$ ). In order to study Mg diffusion in spinels, we modified the nearest neighbor model (normally considered in site percolation estimations) to include occupancies up to the  $3^{rd}$  nearest neighbor (i.e., corner-sharing sites in Table I). Two Mg sites in a given spinel arrangement are considered connected only if the migration channel linking them is open (i.e., the migration barrier is below an upper-limit). Thus, a percolating network of Mg sites is formed solely via open migration channels. Whether a channel is considered open will depend on the migration barrier for Mg hopping through it.

### III. METHODS

The computational approaches to predict properties relevant to cathode materials have recently been reviewed by Urban *et al.*<sup>57</sup> Also, the ability of Density Functional Theory (DFT)<sup>58,59</sup> methods to predict materials with novel properties has been amply demonstrated.<sup>60</sup> As a result, all calculations in this work are done with DFT as implemented in the the Vienna Ab Initio Sim-

ulation Package,<sup>61,62</sup> and employing the Projector Augmented Wave theory.<sup>63</sup> An energy cut-off of 520 eV is used for describing the wave functions, which are sampled on a well-converged  $k$ -point ( $4 \times 4 \times 4$ ) mesh. The electronic exchange-correlation is described by the semi-local Perdew-Burke-Ernzerhof (PBE)<sup>64</sup> functional of the Generalized Gradient Approximation (GGA). Calculations on  $\text{Mg}_x\text{Mn}_2\text{O}_4$  are always initialized with an ideal cubic structure while allowing for potential tetragonal distortions during the geometry relaxation as the spinel can be either cubic ( $x_{\text{Mg}} \sim 0$ ) or tetragonal ( $x_{\text{Mg}} \sim 1$ ) based on the concentration of Jahn-Teller active  $\text{Mn}^{3+}$  ions. The computed  $c/a$  ratio for the tetragonal- $\text{MgMn}_2\text{O}_4$  structure is in excellent agreement with experimental reports<sup>29,65</sup> (see Section S12). For voltage and 0 K phase diagram calculations of  $\text{Mg}_x\text{Mn}_2\text{O}_4$ , the PBEsol exchange-correlation functional<sup>66</sup> is used to improve the description of the energetics,<sup>67</sup> while a Hubbard  $U$  correction of 3.9 eV is added to remove spurious self-interaction of the Mn  $d$ -electrons.<sup>68-70</sup>

The activation barrier calculations are performed with the Nudged Elastic Band (NEB) method.<sup>71,72</sup> The barriers are calculated in a conventional spinel cell (32 anions), which ensures a minimum distance of  $\sim 8 \text{ \AA}$  between the elastic bands and reduces fictitious interactions with periodic images. We verified that migration barriers do not change appreciably ( $< 3\%$  deviation) when equivalent calculations are performed in larger supercells (see Figure S2). Seven images are introduced between the initial and final end points to capture the saddle point and the migration trajectory. All NEB results are based on the PBE functional, without Hubbard  $U$ .<sup>10,11</sup> The migration barriers in spinel- $\text{MgIn}_2\text{S}_4$  are calculated with compensating electrons added as a background charge to ensure charge-neutrality of the structure at non-stoichiometric Mg concentrations.

As migration barriers are calculated in the conventional spinel cell, the degree of inversion ( $i$ ) that can be modeled is constrained by the migration trajectory under consideration, in both the oxide and the sulfide. For example, along Hop 2 (Figure 2b), a  $3/6$  Mg ring site occupancy leads to 3 Mn/In atoms in the  $8a$  sites, and consequently results in  $i \sim 3/8 = 0.375$ . Similarly, the barrier calculations along the  $16d - 48f - 16d$  topol-

ogy (Hops 3, 4, and 5), which require a minimum of 2 Mg atoms in the  $16d$  sites (or 2 Mn/In sites in the  $8a$ ), correspond to  $i \sim 0.25$ .

Monte-Carlo simulations are used to estimate the Mg percolation thresholds ( $x_{crit}$ ) and the fraction of extractable Mg ions ( $x_{ext}$ ). A  $6 \times 6 \times 6$  supercell of the primitive spinel structure is used, which corresponds to 1728 anion atoms (Figure S6 plots convergence behavior with supercell size). In MC simulations, a network of Mg sites is considered percolating when it spans the periodic boundaries of the simulation cell in one or more directions.<sup>73</sup> Inversion in the spinel is introduced during MC sweeps by labelling a number of random  $8a$  and  $16d$  sites, corresponding to the degree of inversion, as part of the “Mg sub-lattice”. For example, the Mg sub-lattice in a normal spinel consists of all  $8a$  sites. However, in an inverted spinel (with the degree of inversion  $i$ ) the Mg sub-lattice will be composed of  $(1-i)\%$  of all  $8a$  sites and  $(i/2)\%$  of all  $16d$  sites.

To evaluate the M composition at which percolation occurs, a MC sweep is performed with the following steps:<sup>73</sup> (i) the supercell is initialized with M atoms in both M and Mg “sub-lattices”, corresponding to a  $M_3X_4$  ( $X = O, S$ ) stoichiometry, (ii) M atoms on the Mg sub-lattice are randomly changed to Mg, (iii) after all Mg sub-lattice sites are changed (i.e., a stoichiometry of  $MgM_2X_4$  is attained), M atoms on the M sub-lattice are randomly flipped to Mg. During an MC sweep, once a Mg atom replacement results in the formation of a percolating network, the current Mg concentration ( $x_{Mg}$ ) is taken as an estimate of the percolation threshold ( $x_{crit}$ ), while for  $x > x_{crit}$ , the fraction of sites within the percolating network,  $x_{ext}$ , is stored. The values of  $x_{crit}$  and  $x_{ext}$  are averaged over 2000 MC sweeps to guarantee well-converged estimates. The effect of vacancies on Mg percolation in the Mn-spinel is captured by initializing the Mg sub-lattice with varying vacancy concentrations, at a given degree of inversion, corresponding to a  $Vac_zMn_{3-z}O_4$  stoichiometry ( $z \leq 1$ ). Whenever vacancies are initialized in a supercell, only the Mn atoms are changed to Mg during a MC sweep.

## IV. RESULTS

### A. $MgMn_2O_4$

Figure 3 plots the ranges of  $Mg^{2+}$  migration barriers in  $Mg_xMn_2O_4$  ( $y$ -axis) for all hops of Figure 2 and Table II, while the raw data is included in Figure S3 of the SI. The migration barriers are calculated with respect to the absolute energies of the end points, nominally identical for a given  $Mg^{2+}$  hop. However, there are a few cases where the end point energies are different, since the local symmetry of the cation decoration is broken differently across the end points (e.g., 3/6 hop in Figure S3b). In such cases, the barrier is reported with respect to the end point with the lowest energy. The

dotted black line in Figure 3 is the upper-limit of the Mg migration barrier, as required for reasonable battery performance,<sup>2</sup> and is used to determine the percolation thresholds (see Section IV C). For a  $Mg_xMn_2O_4$  cathode particle of size  $\sim 100$  nm being (dis)charged at a C/3 rate at  $60^\circ C$ , the migration barrier upper-limit is  $\sim 750$  meV (the upper-limit decreases to  $\sim 660$  meV at 298 K).<sup>2</sup> Since full-cell Mg batteries so far have displayed superior performance at  $\sim 60^\circ C$  than at  $25^\circ C$ ,<sup>1,74</sup> the value of  $\sim 750$  meV has been used as the cut-off to differentiate “open” and “closed”  $Mg^{2+}$  migration channels. In terms of notations, the fractions used in Hop 2 (e.g., 1/6, 2/6, etc., yellow rectangle in Figure 3) correspond to the fraction of  $16d$  ring sites (Figure 2b) that are occupied by  $Mg^{2+}$ . The terms “8a empty” and “8a full” along Hops 3, 4, and 5 in Figure 3 indicate that the corner- $8a$  sites (Figures 2c, d, and e) are vacant and occupied by cations, respectively.  $x_{Mg}$  in Figure 3 is the Mg concentration in the cell used for the barrier estimation, corresponding to the “dilute Mg” ( $x_{Mg} \sim 0$ , solid red lines) and “dilute vacancy” ( $x_{Mg} \sim 1$ , dashed blue lines) limits.

Mg migration barriers along Hop 1 (*tet* – *oct* – *tet*, normal spinel) at the dilute Mg and dilute vacancy limits are  $\sim 717$  meV and  $\sim 475$  meV, respectively (red rectangle in Figure 3), in good agreement with previous studies.<sup>8,11,75</sup> Note that the dilute Mg (vacancy) limit for Hop 1 corresponds to the regime when no  $8a$  sites, other than those required to model the hop, are occupied by Mg (vacancies). Since the migration barriers at both Mg concentration limits are below  $\sim 750$  meV, Hop 1 is always open for Mg migration. Barriers along Hop 2 (yellow rectangle in Figure 3) decrease initially with Mg occupation of the  $16d$  ring sites ( $\sim 393$  meV at 2/6 vs. 536 meV at 1/6) before increasing beyond 750 meV at 5/6 and 6/6 Mg. The non-monotonic variation of the migration barriers along Hop 2 is due to the gradual destabilization of the  $16c$  site. The increasing instability of the  $16c$  also changes the migration energy profile (Figure S3b) from “valley”-like<sup>8</sup> at 1/6 Mg to “plateau”-like at 5/6 Mg. Figure S14 shows the Mg migration barriers along Hop 2 when the ring sites are occupied by vacancies instead of  $Mg^{2+}$ .

In the case of the *oct* – *tet* – *oct* Hops 3 and 4 (green and cyan rectangles in Figure 3), which respectively have *tet* Mg and Mn edge-sharing with the intermediate  $48f$  site, the barriers vary drastically based on Mg content and occupancy of the corner- $8a$  sites. For example, at (i)  $x_{Mg} \sim 0$  and vacant corner- $8a$ , the barrier along Hop 3 ( $\sim 592$  meV) is well below the upper-bound of 750 meV, while the barrier is comparable along Hop 4 ( $\sim 743$  meV). At (ii)  $x_{Mg} \sim 0$  and cation-occupied corner- $8a$ , the barriers along Hops 3 and 4 increase significantly ( $\sim 1388$  meV and  $\sim 1418$  meV) and surpass the upper-limit set for open channels. Eventually, at (iii)  $x_{Mg} \sim 1$  (cation-occupied corner- $8a$ ), the barriers decrease to  $\sim 845$  meV and  $\sim 784$  meV along Hops 3 and 4, respectively. Note that the barriers along Hops 3 and 4 in Figure 3 are calculated at a degree of inversion,  $i \sim 0.25$ . At a higher degree of inversion ( $i \sim 1$ ) and  $x_{Mg} \sim 1$  (cation-occupied

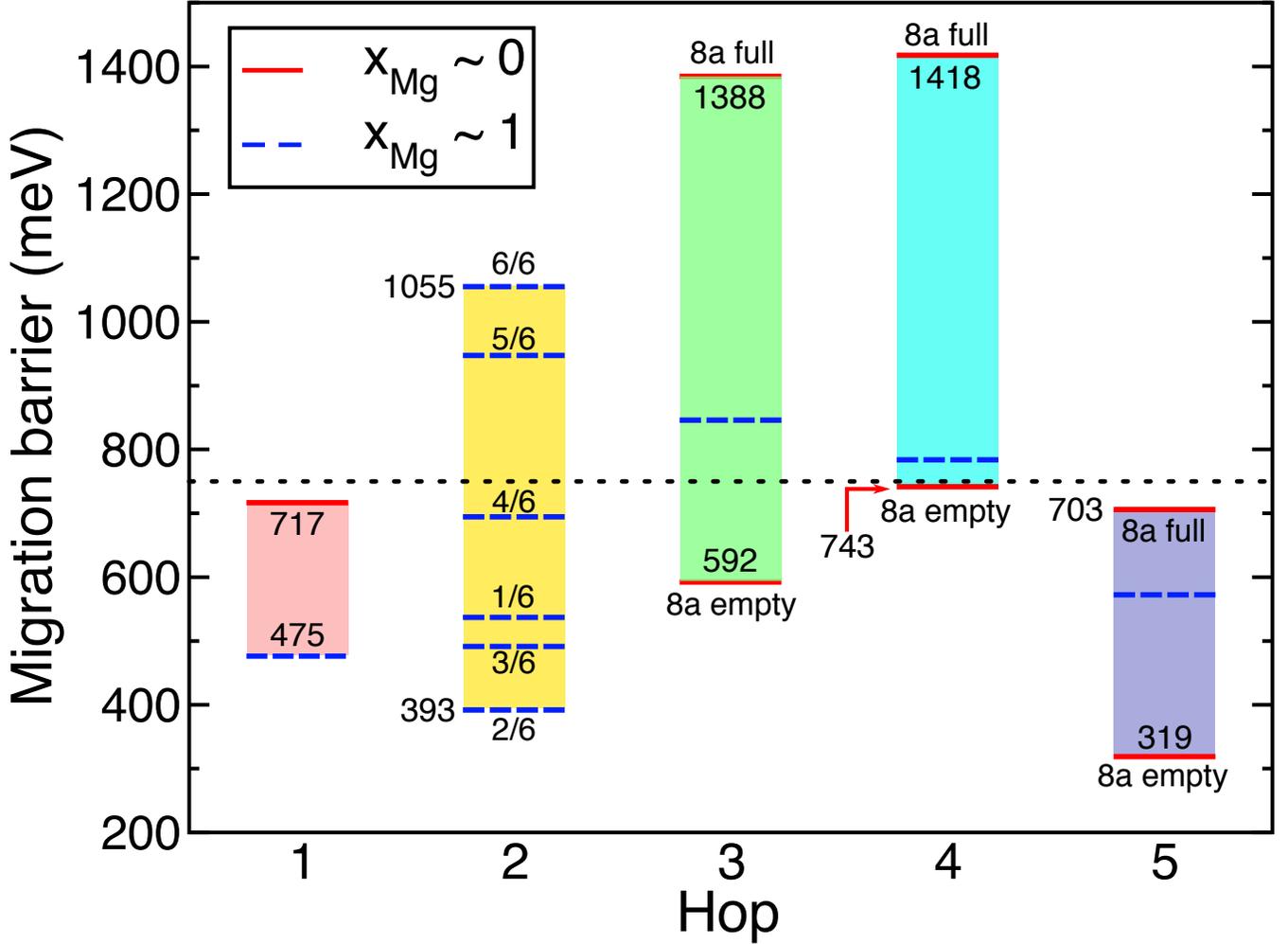


FIG. 3: Ranges of  $\text{Mg}^{2+}$  migration barriers along the hops considered in spinel- $\text{Mg}_x\text{Mn}_2\text{O}_4$ . The dotted black line indicates the upper-limit of migration barriers ( $\sim 750$  meV) used to distinguish open and closed migration channels in percolation simulations. Solid red and dashed blue lines correspond to dilute Mg ( $x_{\text{Mg}} \sim 0$ ) and dilute vacancy ( $x_{\text{Mg}} \sim 1$ ) limits. Fractions along Hop 2 indicate the occupancy of  $\text{Mg}^{2+}$  in the 16d ring sites, while the legend “8a full (empty)” corresponds to cation-occupied (vacant) corner-8a sites along Hops 3 – 5. The barriers along Hop 1 are calculated at  $i \sim 0$ , while Hops 3 – 5 have been done at  $i \sim 0.25$ . Along Hop 2,  $i$  varies with Mg occupancy of the ring sites, ranging from  $i \sim 0.125$  at 1/6 Mg to  $i \sim 0.75$  at 6/6 Mg. The raw data from Nudged Elastic Band calculations are displayed in Figure S3 of the SI.

corner-8a), the barrier is  $\sim 1039$  meV along Hop 4 (Figure S5). Hence, from the data of Figure 3, Hop 3 is considered closed for Mg migration whenever the corner-8a sites are cation-occupied, while Hop 4 is always considered a closed channel.

Mg migration barriers decrease significantly if the edge-8a is vacant (i.e., along Hop 5). For example, the migration barriers along Hop 5 (purple rectangle in Figure 3) are well below that of Hops 3 and 4 across the scenarios of (i) low Mg, vacant corner-8a (319 meV for Hop 5 vs. 592 and 743 meV for Hops 3 and 4, respectively), (ii) low Mg, cation-occupied corner-8a (703 meV vs. 1388 and 1418 meV), and (iii) high Mg, cation-occupied corner-8a (570 meV vs. 845 and 784 meV). Hence, Hop 5 is always open for Mg migration, since the barriers are below the

upper limit of 750 meV.

In summary, the *tet* – *oct* – *tet* pathway (Hops 1 and 2) remains open for Mg migration in  $\text{MgMn}_2\text{O}_4$  until a high degree of Mg occupation on the 16d ring sites (i.e.,  $\geq 5/6$  Mg) is present, which corresponds to high degrees of inversion ( $i > 0.625$ ). The *oct* – *tet* – *oct* pathway is open only when the edge-8a is vacant (Hop 5) or when the corner-8a are vacant with Mg in the edge-8a (Hop 3).

## B. $\text{MgIn}_2\text{S}_4$

Figure 4 plots the  $\text{Mg}^{2+}$  migration barriers in  $\text{MgIn}_2\text{S}_4$  for the hops of Figure 2 (the raw data are shown in Figure S4). Since we consider  $\text{MgIn}_2\text{S}_4$  as an ionic con-

ductor, off-stoichiometric Mg concentrations are not of interest. Hence, all hops in Figure 4 are evaluated at the dilute vacancy limit ( $x_{\text{Mg}} \sim 1$ , dashed blue lines in Figure 4). The fractions used (1/6, 2/6, etc.) in Figure 4 are the number of 16*d* ring sites occupied by  $\text{Mg}^{2+}$  in Hop 2. Along Hops 3 – 5, we use cation-occupied corner-8*a* sites (i.e., “8*a* full” in Figures S4c, d, and e). The upper-limit of the Mg migration barrier for classifying open and closed migration channels (as indicated by the dotted black line in Figure 4) is set to  $\sim 500$  meV, based on migration barriers of  $\sim 400 - 500$  meV observed in fast Li-ion conductors, such as Garnets and Si-based thio-LISICONs.<sup>41</sup>

In the case of Hop 1, the barrier is  $\sim 447$  meV, well below the upper limit of  $\sim 500$  meV. Mg migration barriers along Hop 2 (yellow rectangle in Figure 4) follow trends similar to that of  $\text{MgMn}_2\text{O}_4$  (Figure 3). For example, at low Mg occupation of the ring sites (1/6 or 2/6 Mg), the barrier is below the limits for percolating diffusion, before increasing beyond 500 meV at higher Mg content in the ring sites ( $> 3/6$  Mg). Also, the shape of the migration energy curve changes from a “valley” at 1/6 Mg (solid black line in Figure S4b) to a “plateau” beyond 2/6 Mg (solid red line in Figure S4b), indicating that the 16*c* site becomes progressively unstable with increasing Mg occupation of the ring 16*d*.

Along the 16*d* – 48*f* – 16*d* pathways (Hops 3, 4 and 5), the migration barriers are always higher than 500 meV, irrespective of the occupancy of the edge-8*a*. Indeed, the magnitude of the barriers are  $\sim 683$  meV,  $\sim 531$  meV, and  $\sim 504$  meV for Mg-occupied, In-occupied and vacant edge-8*a*, respectively, indicating that the *oct* – *tet* – *oct* pathway will not be open for  $\text{Mg}^{2+}$  migration.

### C. Percolation thresholds

Based on the data of Figures 3 and 4, and the upper limits of Mg migration barriers set for  $\text{MgMn}_2\text{O}_4$  (750 meV) and  $\text{MgIn}_2\text{S}_4$  (500 meV), we compiled a list of conditions that enable the opening of the possible hops in Table III. For example, Hop 1 (8*a* – 8*a*) is open for all values of  $x_{\text{Mg}}$  and *i* for both  $\text{Mg}_x\text{Mn}_2\text{O}_4$  and  $\text{MgIn}_2\text{S}_4$ . Both the oxide and the sulfide spinel exhibit high barriers ( $> 1$  eV) for a 16*d* – 8*a* hop (Figure S8), which would limit Mg transfer between an octahedral 16*d* site and an adjacent tetrahedral 8*a* site. Thus, in our percolation simulations, the 8*a* – 8*a* (Hops 1 and 2) and the 16*d* – 16*d* (Hops 3, 4, and 5) channels remain decoupled, and a percolating network consists solely of either 8*a* – 8*a* or 16*d* – 16*d* channels.

Figures 5a and b plot the percolation threshold ( $x_{\text{crit}}$ , black lines), at various degrees of inversion (*i*) in  $\text{Mn}_{3-x}\text{O}_4$  and  $\text{In}_{3-x}\text{S}_4$ . The dashed yellow lines indicate the stoichiometric spinel, i.e., M:X = 2:4. The blue (red) shaded region corresponds to Mg concentration ranges which do (do not) exhibit percolation. The x-axis in Figure 5 begins at a  $\text{M}_3\text{X}_4$  (i.e., 50% M-excess or 100%

TABLE III: Summary of rules used during percolation simulations with the conditions for an open channel. The upper limit of migration barriers used to distinguish between open and closed channels is 750 meV and 500 meV for  $\text{MgMn}_2\text{O}_4$  and  $\text{MgIn}_2\text{S}_4$ , respectively.

Hop	Topology	Open under condition
<b><math>\text{MgMn}_2\text{O}_4 - 750 \text{ meV}</math></b>		
1	8 <i>a</i> – 16 <i>c</i> – 8 <i>a</i>	Always open
2	8 <i>a</i> – 16 <i>c</i> – 8 <i>a</i>	Max. 4/6 ring sites with Mg
3	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Corner 8 <i>a</i> vacant
4	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Always closed
5	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Always open
<b><math>\text{MgIn}_2\text{S}_4 - 500 \text{ meV}</math></b>		
1	8 <i>a</i> – 16 <i>c</i> – 8 <i>a</i>	Always open
2	8 <i>a</i> – 16 <i>c</i> – 8 <i>a</i>	Max. 2/6 ring sites with Mg
3	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Always closed
4	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Always closed
5	16 <i>d</i> – 48 <i>f</i> – 16 <i>d</i>	Always closed

Mg-deficient) configuration and spans concentrations up to  $\text{Mg}_{1.5}\text{M}_{1.5}\text{X}_4$  (i.e., 25% M-deficient, 50% Mg-excess). Generally, percolation thresholds in the M-excess domain (i.e.,  $x_{\text{crit}} < 1$ ) are desirable as this implies that the stoichiometric spinel will possess percolating networks and will facilitate macroscopic Mg transport.

In the case of cathodes ( $\text{Mn}_2\text{O}_4$ ), Mg deintercalation from the framework creates vacancies, which can facilitate the formation of Mg percolating networks by opening certain migration channels (e.g., Hop 5 in  $\text{MgMn}_2\text{O}_4$ , Figure 3). Therefore, we explored the variation of the percolation threshold with vacancy concentration (“z” in Figure 5a) in the Mn-spinel. For the sake of simplicity, x in Figure 5 refers to the sum of Mg and vacancy concentrations. For example,  $x = 1$  and  $z = 0.5$  (green circle on the dashed black line) in Figure 5a indicates a composition of  $\text{Mg}_{0.5}\text{Vac}_{0.5}\text{Mn}_2\text{O}_4$ , while  $x = 0.6$  and  $z = 0$  (green square) corresponds to the M-excess spinel- $\text{Mg}_{0.6}\text{Vac}_0\text{Mn}_{2.4}\text{O}_4$ .

The percolation threshold in the absence of vacancies ( $z = 0$ ) is indicated by the solid black line in Figure 5a. When vacancies are introduced, the threshold decreases, as indicated by the  $x_{\text{crit}}$  at  $z = 0.4$  (dotted black line) or 0.5 (dashed) consistently exhibiting lower values than  $x_{\text{crit}}$  at  $z = 0$  in Figure 5a. For example, at  $x = 0.8$  and  $i = 0.5$  (indicated by the green star in Figure 5a), the spinel does not form a percolating network when there are no vacancies ( $z = 0$ ,  $\text{Mg}_{0.8}\text{Mn}_{2.2}\text{O}_4$ ), since  $x_{\text{crit}} \sim 0.88 > 0.8$ . However, the structure can percolate Mg when vacancies are introduced ( $z = 0.5$ ,  $\text{Mg}_{0.3}\text{Vac}_{0.5}\text{Mn}_{2.2}\text{O}_4$ ), as  $x_{\text{crit}}$  reduces to  $\sim 0.52 < 0.8$ . In a case such as this, the initial cathode structure may not be percolating, but introducing vacancies in the initial part of the charge can create a percolating zone on the cathode particle surface through which further Mg-removal can occur. However, upon discharge the perco-

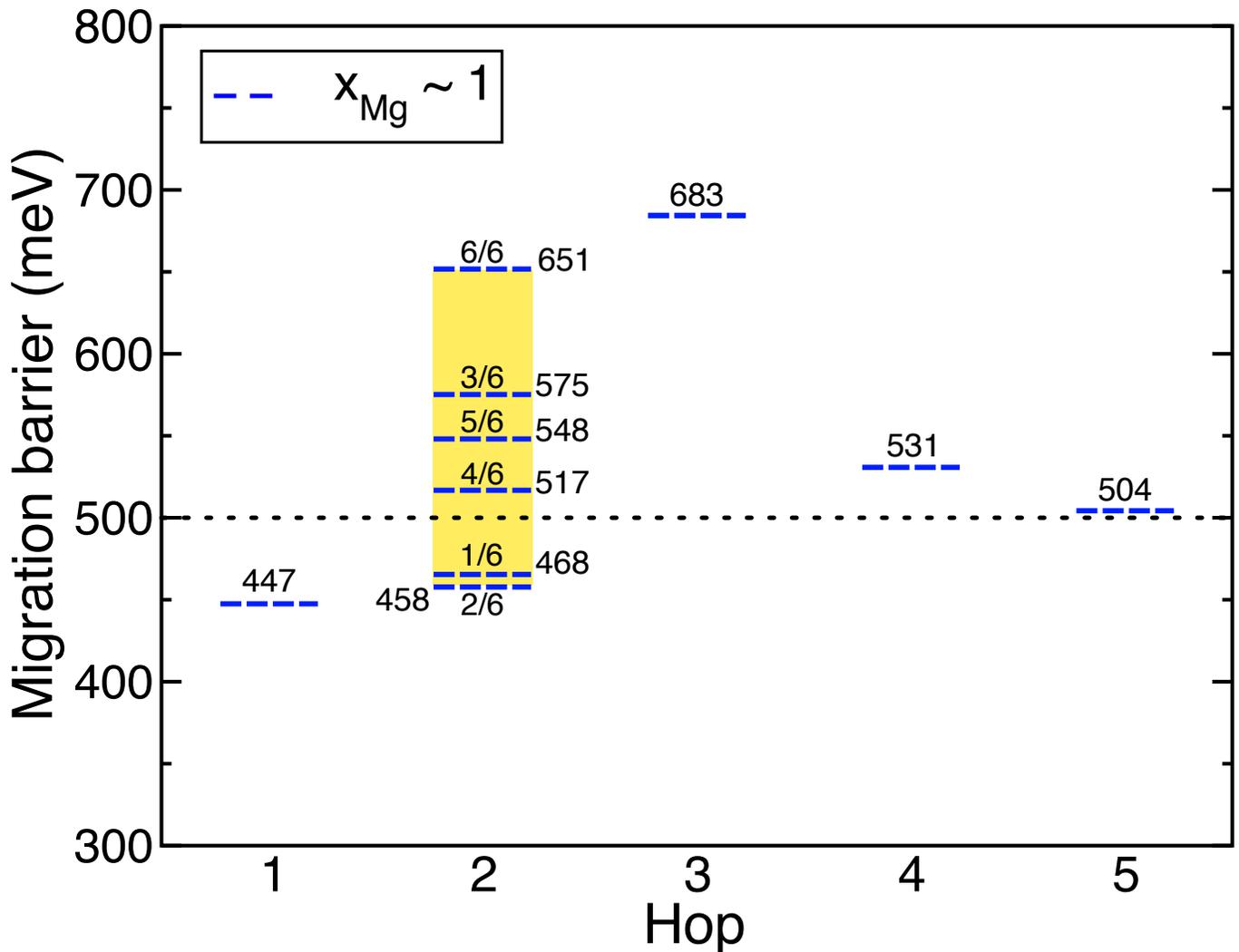


FIG. 4:  $\text{Mg}^{2+}$  migration barriers along each possible hop in spinel- $\text{MgIn}_2\text{S}_4$ . The dotted black line indicates the upper-limit of migration barriers ( $\sim 500$  meV) used to distinguish open and closed migration channels in percolation simulations. Dashed blue lines indicate the dilute vacancy ( $x_{\text{Mg}} \sim 1$ ) limit. Fractions along Hop 2 indicate the occupancy of  $\text{Mg}^{2+}$  in the  $16d$  ring sites, while the corner- $8a$  sites are cation-occupied across Hops 3 – 5. The barrier along Hop 1 is calculated at  $i \sim 0$ , while Hops 3 – 5 have been done at  $i \sim 0.25$ . Along Hop 2,  $i$  varies with Mg occupancy of the ring sites, ranging from  $i \sim 0.125$  at  $1/6$  Mg to  $i \sim 0.75$  at  $6/6$  Mg. The raw data from Nudged Elastic Band calculations are displayed in Figure S4.

lating structure could easily become non-percolating if polarization increases the surface Mg concentration too rapidly.

At any degree of inversion, the magnitude of  $x_{crit}$  varies non-monotonically and reduces only up to a vacancy content,  $z = 0.4$  or  $0.5$  (see Figure S7a). Indeed, at  $x = 0.8$  and  $i = 0.5$  (green star), an increase in  $z$  beyond  $0.5$  (such as  $z = 0.6$ ,  $\text{Mg}_{0.2}\text{Vac}_{0.6}\text{Mn}_{2.2}\text{O}_4$ ), causes the  $x_{crit}$  to increase to  $\sim 0.6$ , but the spinel continues to percolate. Thus, the shaded grey region in Figure 5a, which is bound by the  $z = 0.4$ ,  $0.5$  and  $0$  lines represents the extent of variation of  $x_{crit}$  with vacancy content in the cathode. Notably, the lowest value of  $x_{crit}$  is obtained at  $z = 0.4$  for  $0 \leq i \leq 0.35$  and  $0.595 \leq i < 0.77$ , and at  $z = 0.5$  for  $0.35 \leq i \leq 0.595$ , respectively.

The stoichiometric  $\{\text{Mg}/\text{Vac}\}\text{Mn}_2\text{O}_4$  spinel at  $i = 0$  (dashed yellow line in Figure 5a), permits macroscopic Mg diffusion, since the percolation threshold ( $x_{crit} \sim 0.44$  for  $z = 0 - 0.4$ ) is in the Mn-excess domain (i.e.,  $x_{crit} < 1$ ). When vacancies are absent in the stoichiometric spinel ( $z = 0$ ), which corresponds to the discharged  $\text{MgMn}_2\text{O}_4$  composition, the structure percolates Mg up to  $i \sim 0.55$ . Upon charging, the presence of vacancies ( $z = 0.5$ ) enables Mg percolation within  $\text{Mg}_{0.5}\text{Vac}_{0.5}\text{Mn}_2\text{O}_4$  up to  $i \sim 0.59$ . At higher degrees of inversion ( $0.59 < i < 0.77$ ), the oxide spinel requires Mn-deficient concentrations (i.e.,  $x > 1$ ) to facilitate Mg percolation, as illustrated by  $x_{crit} \sim 1.05 - 1.13$  ( $z = 0.5 - 0$ ) at  $i = 0.6$ . At  $i > 0.77$ , the oxide does not form a percolating Mg network at any level of Mn-deficiency

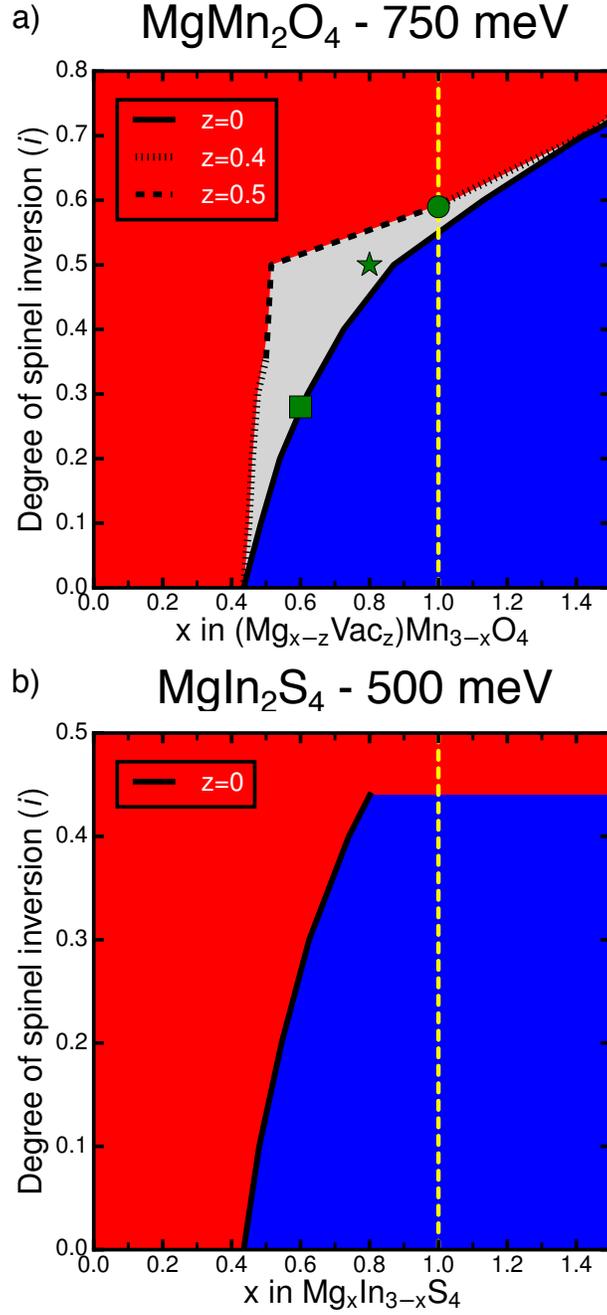


FIG. 5: The critical concentration for Mg percolation ( $x_{crit}$ ) in the  $(\text{Mg}_{x-z}\text{Vac}_z)\text{Mn}_{3-x}\text{O}_4$  (a) and  $\text{Mg}_x\text{In}_{3-x}\text{S}_4$  (b) spinels are plotted as black lines at different degrees of spinel inversion  $i$ . The stoichiometric spinel concentration ( $\text{M}:\text{X} = 2:4$ ) is indicated by the dashed yellow lines. Note that the zero on the  $x$ -axis corresponds to a stoichiometry of  $\text{M}_3\text{X}_4$  ( $\text{M} = \text{Mn}/\text{In}$  and  $\text{X} = \text{O}/\text{S}$ ).  $z$  indicates the vacancy concentration in the structure. The shaded red (blue) region in both panels indicates the Mg concentration range where macroscopic Mg diffusion is not possible (possible). The shaded grey region in panel (a) refers to the range of variation of the percolation threshold with vacancy content in the oxide cathode. The green circle, square and star in panel (a) correspond to sample scenarios discussed in the text.

(for  $z \leq 1$ ) in the lattice.

In stoichiometric ionic conductors, such as  $\text{MgIn}_2\text{S}_4$ , the vacancy concentration is low and therefore vacancies are not expected to play a major role in macroscopic Mg transport. Specifically in  $\text{MgIn}_2\text{S}_4$ , vacancies do not

open additional migration channels, as indicated by the closed Hop 5 in Figure 4. Indeed, the percolation threshold in the In-spinel does not change up to a vacancy content,  $z = 0.2$  in the structure (see Figure S7b). At  $z = 0$ , the  $x_{crit}$  in  $\text{In}_{3-x}\text{S}_4$  (solid black line in Figure 5b)

increases continuously with increase in inversion, with  $x_{crit} \sim 0.435$ , and 0.74 at  $i = 0$ , and 0.4, respectively. Thus, at low  $i$ , stoichiometric  $\text{MgIn}_2\text{S}_4$  should exhibit significant ionic conductivity. However, at higher degrees of inversion ( $i > 0.44$ ), the sulfide spinel does not form percolating networks at any Mg-concentration, owing to the absence of open  $16d - 16d$  channels in combination with the  $8a - 8a$  channels being closed beyond 2/6 Mg ring site occupancy (Table III).

In general, mobility requirements in an ionic conductor are more stringent than in a cathode, consistent with the stricter cut-off of 500 meV we applied to the migration barriers in  $\text{MgIn}_2\text{S}_4$ .<sup>41,76</sup> Indeed, a sulfide spinel Mg-cathode (such as  $\text{Mg}_x\text{Ti}_2\text{S}_4$ <sup>74</sup>) exhibiting similar activation barriers with inversion as  $\text{MgIn}_2\text{S}_4$  will not suffer from any percolation bottlenecks, since the barriers across all cation arrangements are well below the milder 750 meV cut-off set for cathodes (Figure 4).

#### D. Impact of inversion on cathode electrochemistry

Under ideal conditions, the structure of an ionic conductor (such as  $\text{MgIn}_2\text{S}_4$ ) should not undergo significant changes during operation. Thus, the extent of inversion should, in principle, be measured using characterization experiments post-synthesis (the calculated formation energies of various inverted configurations in spinel  $\text{MgIn}_2\text{S}_4$  are plotted in Figure S11). However in a cathode material such as  $\text{Mg}_x\text{Mn}_2\text{O}_4$ , which can generate mobile  $\text{Mn}^{2+}$  ions (Figure S9) through disproportionation of  $\text{Mn}^{3+}$ , the degree of inversion ( $i$ ) can change during electrochemical cycling.<sup>16,34</sup> Consequently, structural changes in a cathode during cycling should manifest themselves as changes in the voltage profile and observed capacity, which can be benchmarked with theoretical predictions.<sup>2,21</sup> To evaluate the effect of inversion on the voltage profile of  $\text{Mg}_x\text{Mn}_2\text{O}_4$ , we calculated the phase diagram and energy of the intercalation system at 0 K as a function of Mg content under various degrees of inversion.<sup>16,17,21,77</sup>

To evaluate the ground state hull of the  $\text{Mg}_x\text{Mn}_2\text{O}_4$  system, we enumerated over 400 Mg-vacancy configurations, at different Mg concentrations ( $x_{\text{Mg}} = 0, 0.25, 0.5, 0.75$  and 1) and different degrees of inversion ( $i = 0, 0.25, 0.5, 0.75$  and 1). Figure 6a displays structures with formation energies ( $y$ -axis) below 200 meV/ $\text{Mn}_2\text{O}_4$  at different Mg concentrations ( $x$ -axis), and the formation energies of all the Mg-vacancy configurations considered are plotted in Figure S10 of the SI. Notably, formation energies in Figure 6a have been referenced to the non-inverted ( $i = 0$ ), empty  $\text{Mn}_2\text{O}_4$  and magnesiated ( $\text{MgMn}_2\text{O}_4$ ) spinel configurations. For each configuration, the degree of inversion is indicated by the corresponding symbol used, ranging from  $i = 0$  (black circles) to  $i = 1$  (red stars).

Overall, the  $\text{Mg}_x\text{Mn}_2\text{O}_4$  system is phase separating at 0 K across non-inverted ( $i = 0$ )  $\text{MgMn}_2\text{O}_4$  and

$\text{Mn}_2\text{O}_4$  domains, since the ground state hull of the system (dashed black line in Figure 6a) only exhibits two configurations (i.e.,  $\text{MgMn}_2\text{O}_4$  and  $\text{Mn}_2\text{O}_4$ ). Some solubility at low Mg content may be possible given the low positive mixing energy at  $x_{\text{Mg}} = 0.25$  for the non-inverted spinel ( $E_{\text{formation}} \sim 14$  meV/ $\text{Mn}_2\text{O}_4$ ). At higher Mg content, the formation energies are very high for the non-inverted spinel (Figure S10), making a solid solution behavior very unlikely. Inversion becomes likely to occur at intermediate Mg compositions, as the low positive formation energies are on the scale of the configurational entropy. For example,  $E_{\text{formation}} \sim 11$  meV/ $\text{Mn}_2\text{O}_4$  at  $i = 0.25$  and  $x_{\text{Mg}} = 0.5$  (green square at  $x = 0.5$  in Figure 6a). Hence, inversion at intermediate states of magnesiation is likely. While Mg by definition has to be mobile in  $\text{Mn}_2\text{O}_4$  to operate as a cathode, Mn mobility, which is required for spinel inversion to occur, depends strongly on its valence state.<sup>16,34</sup> Typically,  $\text{Mn}^{3+}$  can be mobile through a temporary disproportionation mechanism, generating mobile  $\text{Mn}^{2+}$  (Figure S9).<sup>16,34</sup>

Figure 6b plots the average voltages as a function of  $x_{\text{Mg}}$  at different  $i$  by taking the lowest  $E_{\text{formation}}$  configuration at each  $i$  and  $x_{\text{Mg}}$ .<sup>77</sup> The average voltage for Mg insertion in the non-inverted ( $i = 0$ ) configuration is  $\sim 2.84$  V (dashed black line in Figure 6b), in agreement with previous theoretical estimates.<sup>11,78</sup> Inversion does increase the average insertion voltage (averaged over  $x_{\text{Mg}} = 0$  to 1) marginally compared to the normal spinel, with specific values of  $\sim 2.92, 2.99, 2.97$  and  $2.99$  V at  $i = 0.25, 0.5, 0.75$  and 1, respectively. Notably, the phase behavior of the  $\text{Mg}_x\text{Mn}_2\text{O}_4$  system under inversion will be different compared to the normal spinel due to the formation of metastable inverted states at intermediate Mg compositions.

The extractable Mg content ( $x_{\text{ext}}$ , see Section II B), obtained as a function of inversion from our Monte-Carlo simulations, indicates the extractable capacity of a cathode particle, and is shown in Figure 6c for stoichiometric  $\text{MgMn}_2\text{O}_4$ . The  $y$ -axis indicates the % of the cathode's theoretical capacity ( $\sim 270$  mAh/g for  $\text{MgMn}_2\text{O}_4$ ), that can be cycled reversibly. At low degrees of inversion, the extractable capacity in the stoichiometric spinel decreases roughly linearly with the degree of inversion, reaching  $\sim 41\%$  ( $\sim 110$  mAh/g) at  $i = 0.4$ . The extractable Mg content decreases more rapidly from  $i = 0.4$  to  $i = 0.5$ , before stabilizing around  $\sim 15\%$  ( $\sim 40$  mAh/g) between  $i = 0.5$  and 0.6. Eventually, none of the Mg becomes extractable beyond  $i = 0.61$ , reflecting the trends in the percolation thresholds ( $x_{\text{crit}} \sim 0.59$  at stoichiometric  $\text{MgMn}_2\text{O}_4$ , Figure 5a) at high degrees of inversion. Note that, the overall amount of cyclable Mg from a cathode particle is influenced both by the extractable Mg (shown in Figure 6c) and by the phase behavior as a function of  $x_{\text{Mg}}$ . For example, if the Mg removal occurs via a two-phase reaction (as is the case for the non-inverted spinel), then the presence of a non-percolating layer on the surface may prevent extraction of Mg from the bulk, even if percolation conditions are

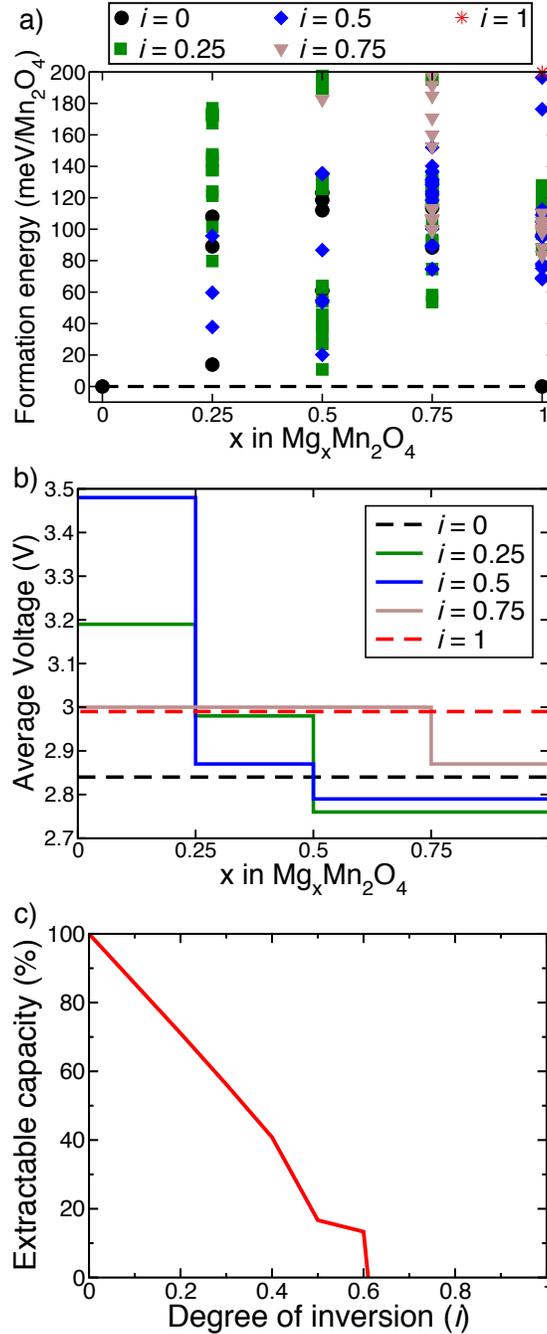


FIG. 6: (a) Ground state hull (or 0 K phase diagram) of the  $\text{Mg}_x\text{Mn}_2\text{O}_4$  system, with the zero of the formation energy referenced to the non-inverted ( $i=0$ ) magnesiated ( $\text{MgMn}_2\text{O}_4$ ) and empty ( $\text{Mn}_2\text{O}_4$ ) spinel configurations. (b) Average voltage curves under  $i$  in  $\text{Mg}_x\text{Mn}_2\text{O}_4$ , obtained using the lowest formation energy structures at each  $i$  across Mg concentrations. (c) The percentage of the theoretical capacity that can be reversibly extracted is plotted as a function of inversion in stoichiometric  $\text{MgMn}_2\text{O}_4$ .

still favorable in the bulk material.

## V. DISCUSSION

In this work, we have used DFT-based NEB calculations to assess the changes in the activation barrier

for  $\text{Mg}^{2+}$  migration arising from inversion in both oxide ( $\text{MgMn}_2\text{O}_4$ ) and sulfide ( $\text{MgIn}_2\text{S}_4$ ) structures. From our results (Figures 3 and 4), we can conclude that inversion has a significant impact on both oxides and sulfides, by opening and closing specific migration trajectories. In order to extrapolate the impact of the various  $\text{Mg}^{2+}$  migration barriers on macroscopic Mg diffusion, we esti-

mated the percolation thresholds under different degrees of spinel inversion. Furthermore, we analyzed the impact of spinel inversion on cathode properties of  $\text{Mg}_x\text{Mn}_2\text{O}_4$  by evaluating the average voltages and practical capacities at different degrees of inversion.

### A. Factors influencing barriers in $\text{MgMn}_2\text{O}_4$

Trends from activation barriers of Figure 3 suggest that Mg migration along the  $8a - 16c - 8a$  pathways (Hops 1 and 2) can improve significantly with Mg occupation of the  $16d$  ring sites (up to 4/6 Mg), at low degrees of inversion. Additionally, the  $16d - 48f - 16d$  channels open for Mg migration whenever the edge- $8a$  is vacant. However, high degrees of inversion detrimentally affect  $\text{Mg}^{2+}$  motion, due to the closing of both  $16d - 16d$  (corner- and edge- $8a$  become occupied by the metal cation) and  $8a - 8a$  channels (high migration barriers at high Mg in the ring sites). Although we have specifically considered the case of spinel- $\text{Mg}_x\text{Mn}_2\text{O}_4$ , similar trends can be expected for other oxide spinels, given the similarity in Mg migration barriers along Hop 1 with different  $3d$ -metals.<sup>11</sup>

Previous studies have used electrostatic considerations to partially explain trends in  $\text{Li}^+$  activation barriers in a  $\text{Mn}_2\text{O}_4$  spinel.<sup>46</sup> Indeed, the reduction in Mg migration barriers along Hops 1, 3, 4, and 5 (Figure 3) with increasing Mg concentration can be attributed to lower electrostatic repulsions at the corresponding intermediate sites caused by the reduction of  $\text{Mn}^{4+}$  to  $\text{Mn}^{3+}$ . For example, the barrier reduces from 717 to 475 meV along Hop 1 and 1388 to 845 meV along Hop 3, as  $x_{\text{Mg}}$  increases from  $\sim 0$  to  $\sim 1$ . However,  $\text{Mg}^{2+}$  activation barriers generally depend on steric and bonding constraints in addition to electrostatics, which are often difficult to deconvolute over a range of NEB calculations. For example, the  $\text{Mg}^{2+}$  activation barriers across Hop 2 (yellow bar in Figure 3) at low Mg occupation in the ring sites (1/6, 2/6) are lower than Hop 1 (red bar, Figure 3), which may be attributed to reduced electrostatic repulsion on the intermediate  $16c$  (due to  $\text{Mg}^{2+}$  replacing higher valent Mn in the ring sites). However, barriers along Hop 2 increase beyond Hop 1 and eventually beyond the limit of  $\sim 750$  meV at higher Mg in the ring sites (5/6, 6/6), despite lower electrostatic repulsion. Thus, the high Mg content in the ring sites decreases the stability of the intermediate  $16c$ . One possible reason for the instability of the  $16c$  (e.g., in the case of 6/6 Mg in Hop 2) is quantified by longer (DFT-based)  $\sim 2.3$  Å Mg-O bonds, compared to  $\sim 2.08$  Å in  $16d$  with Mg (along the same hop) and  $\sim 2.13$  Å in rocksalt MgO.<sup>78</sup>

For the  $16d - 48f - 16d$  hops in Figure 3 (Hops 3–5), electrostatic effects are more dominant than for the *tet*–*oct*–*tet* hops (Hops 1, 2), primarily due to the intermediate  $48f$  edge-sharing with an  $8a$ . Indeed, the cation

centers in edge-sharing tetrahedra are closer ( $\sim 2.15$  Å experimentally between  $48f$  and  $8a$  in an ideal  $\text{LiMn}_2\text{O}_4$ -spinel<sup>79</sup>) than in edge-sharing octahedra ( $\sim 2.88$  Å between  $16c$  and  $16d$ ). Consequently, the Mg barriers are consistently lower with a vacant edge- $8a$  (Hop 5, Figure 3) compared to Mg/Mn-filled edge- $8a$  (Hops 3, 4 in Figure 3). Also,  $\text{Mg}^{2+}$  activation barriers (at  $x_{\text{Mg}} \sim 0$ ) increase significantly when the corner- $8a$  sites are cation-occupied rather than vacant (Figure 3). A closer look at the cation-cation distances across corner-sharing  $48f$  and  $8a$  ( $\sim 2.88$  Å in ideal  $\text{LiMn}_2\text{O}_4$ ) reveals that the corner-sharing tetrahedra within a spinel framework may experience electrostatic repulsion as high as edge-shared octahedra (i.e.,  $16c$  and  $16d$ ). Thus, the combination of cation-cation repulsion arising from both edge- and corner- $8a$  sites results in the high barriers along Hops 3 and 4.

### B. Barriers in sulfides vs. oxides

Activation barriers calculated in  $\text{MgIn}_2\text{S}_4$  (Figure 4) exhibit similar trends to  $\text{MgMn}_2\text{O}_4$  (Figure 3), resulting from analogous trends in electrostatics, steric and bonding environments. However, the absolute changes in barriers in the sulfide are remarkably lower than the oxide. For example, the absolute difference between the lowest and the highest Mg migration barriers of  $\text{MgMn}_2\text{O}_4$  (at  $x_{\text{Mg}} \sim 1$ ) across Hops 1 through 5 is  $\sim 662$  meV (1055 – 393 meV), while this is a much lower  $\sim 236$  meV (683 – 447 meV) for  $\text{MgIn}_2\text{S}_4$ . Similarly, the barriers along the  $16d - 48f - 16d$  trajectory are far less sensitive to the edge- $8a$  occupancy in the sulfide (504–673 meV) than in the oxide (570–845 meV at  $x_{\text{Mg}} \sim 1$ ). Surprisingly, the migration barrier with an edge- $8a$  occupied by  $\text{Mg}^{2+}$  is higher ( $\sim 683$  meV) than when the edge- $8a$  is occupied by  $\text{In}^{3+}$  ( $\sim 531$  meV), suggesting that the In–S bonding environment screens the higher  $\text{In}^{3+}$  charge better than the Mg–S bonds screen  $\text{Mg}^{2+}$ .

Lower activation barriers for Mg in sulfides have been reported before,<sup>11,12,38</sup> which have been assigned to robust electrostatic screening, high polarizability, higher degree of covalency and large volume per anion of  $\text{S}^{2-}$  compared to  $\text{O}^{2-}$ .<sup>2,76</sup> For example, a  $\text{Mg}_x\text{Ti}_2\text{S}_4$ <sup>74</sup> cathode will not suffer from any percolation bottlenecks, if the barriers across all cation arrangements are similar to the calculated values in  $\text{MgIn}_2\text{S}_4$  (i.e.,  $< 750$  meV, Figure 4). But a more stringent upper-bound of  $\sim 500$  meV on the barrier in a solid-state conductor<sup>41,76</sup> indicates that inversion can significantly affect a sulfide ionic conductor by closing all  $16d - 16d$  channels and several  $8a - 8a$  channels with high Mg in the  $16d$  ring (Figure 4). Since ionic mobility is expected to improve with larger anions and higher covalency (such as  $\text{Se}^{2-}$  compared to  $\text{S}^{2-}$  and  $\text{O}^{2-}$ ), inversion is expected to affect Mg-mobility to a lesser extent in Mg-containing Se-spinels, such as  $\text{MgSc}_2\text{Se}_4$ , compared to oxides and sulfides.

### C. Percolation under inversion

Estimations of percolation thresholds ( $x_{crit}$ ) in the  $Mg_xMn_{3-x}O_4$  system (Figure 5a) indicate that spinel inversion should not detrimentally affect macroscopic  $Mg^{2+}$  diffusion across the structure up to a fairly high degree of inversion,  $i \sim 0.55 - 0.59$ . However, Mg-excess concentrations are required to ensure percolating networks form at  $i = 0.6 - 0.7$ , while the spinel completely ceases to percolate Mg beyond  $i = 0.77$  (Figure 5a). Given the preponderance of conversion reactions under Mg-excess concentrations in the oxide spinel, specifically the decomposition of  $Mg_xMn_{3-x}O_4$  ( $x > 1$ ) into MgO and  $MnO$ ,<sup>2</sup> it is of paramount importance that the chemically synthesizable, stoichiometric  $\{Mg/Vac\}Mn_2O_4$  remains percolating. Efforts should be made to reduce or precisely control the amount of inversion (i.e.,  $i < 0.6$ ), by carefully tuning synthesis temperature and cooling rate<sup>29,30</sup> during  $MgMn_2O_4$  synthesis.

Higher Mg conductivity, as is required for a solid state electrolyte, demands a lower cut-off for the migration barrier along a pathway. In the case of  $MgIn_2S_4$ , where we used a 500 meV cut-off, MC simulations indicate that the stoichiometric spinel should remain percolating up to  $i \sim 0.44$ . However, high degrees of inversion ( $i \sim 0.85$ ) can be observed during  $MgIn_2S_4$  synthesis (Figure S1). As a result, strategies to limit inversion (i.e.,  $i < 0.44$ ) in sulfide spinel ionic conductors, such as chemical doping and careful calibration of synthesis conditions, need to be sought.

### D. Voltages and capacities

Inversion can also significantly impact electrochemical properties, such as phase behavior, average voltages and extractable capacities in an oxide-spinel cathode (Figure 6). For example, the average voltage for Mg intercalation, across  $x_{Mg} = 0 - 1$  in the  $Mn_2O_4$ -spinel, is higher in an inverted spinel compared to a normal spinel (Figure 6b). Mg intercalation experiments in spinel- $Mn_2O_4$  have reported a marginally higher average voltage ( $\sim 2.9$  V)<sup>26</sup> than predicted for the normal spinel ( $\sim 2.84$  V), with extraction voltages as high as  $\sim 3.5$  V during the charging cycle, which might be an indication of the spinel inverting during electrochemistry. Also, the calculated 0 K phase diagram of the Mg- $Mn_2O_4$  system (Figure 6a) suggests that the tendency to invert is the highest at an intermediate Mg concentration, as indicated by low  $E_{formation}$  ( $< 50$  meV/ $Mn_2O_4$ ) configurations with  $i = 0.25$  at  $x_{Mg} = 0.5$ . Hence, the degree of inversion in the Mn-spinel can indeed change dynamically during electrochemical Mg cycling, especially due to the presence of mobile  $Mn^{2+}$  ions (Figure S9). As reported by Ling *et al.*<sup>80</sup>, the mobility of  $Mn^{2+}$  within the spinel can also depend on the local arrangement of  $Mg^{2+}$  ions. Thus, from the data in Figure 6a, we expect the degree of inversion to vary largely between 0 and 0.25 dur-

ing Mg-cycling. Also, previous Mg-cycling experiments in spinel- $Mn_2O_4$  have reported solvent co-intercalation based phase transformations,<sup>28,81</sup> which can be aided by the presence of mobile  $Mn^{2+}$  ions.

Additionally, the first Mg-site that will be (de-)intercalated in the spinel will depend on the degree of inversion on the surface of the cathode particle. For example, if the degree of inversion is  $\sim 0$  on the surface, then  $Mg^{2+}$  ions present in the  $8a$  sites will be de-intercalated first from magnesiated- $MgMn_2O_4$ . Similarly, in a partially inverted surface of a discharged cathode, the  $Mg^{2+}$  ions in  $16d$  sites that are connected via Hop 3 channels will be extracted as well as those in  $8a$  sites connected via Hop 1 and open Hop 2 channels. In the case of a partially inverted surface in a charged- $Mn_2O_4$  cathode, the  $Mg^{2+}$  ions are more likely to first insert into  $16d$  channels connected via Hop 5, since Hop 5 exhibits lower Mg migration barriers compared to Hop 1 (Figure 2) at  $x_{Mg} \sim 0$ .

Since the percolation threshold in the oxide cathode can change with the vacancy concentration during Mg (de)intercalation (Figure 5a), a dynamic change in the degree of inversion during Mg-cycling can cause polarization within the cathode particle. For example, if  $i$  changes from 0.55 to 0.59 while charging the  $MgMn_2O_4$  cathode, during the following discharge the spinel is percolating only up to  $Mg_{0.5}Vac_{0.5}Mn_2O_4$  ( $z = 0.5$  in Figure 5a) at  $i = 0.59$ . For further discharge into the structure, i.e., from  $Mg_{0.5}Vac_{0.5}Mn_2O_4$  to  $MgMn_2O_4$ , a reduction in  $i$  to 0.55 is necessary, which can lead to hysteresis in the voltages during the charge and discharge cycles. Importantly, the extractable Mg content in stoichiometric  $MgMn_2O_4$  decreases continuously with inversion, reaching values of  $\sim 63\%$  (171 mAh/g) and  $\sim 17\%$  (46 mAh/g) at  $i = 0.25$  and  $0.5$  (Figure 6c), respectively. Thus, strategies to minimize changes in  $i$ , during  $Mg^{2+}$  cycling, such as cation-doping of Mn to prevent  $Mn^{2+}$  generation, should be employed to ensure reversible Mg (de)intercalation.

## VI. CONCLUSION

Spinel is a promising material in the development of multivalent battery electrodes and solid electrolytes but are prone to antisite disorder in the form of spinel inversion. With the example of two prototypical oxide and sulfide spinels,  $MgMn_2O_4$  (cathode) and  $MgIn_2S_4$  (solid electrolyte), we demonstrated that inversion can significantly impact both Mg-ion mobility and electrochemical properties. Using first-principles calculations, we analyzed the migration barrier for  $Mg^{2+}$  hopping in different local cation arrangements, and found that inversion can both open and close select migration pathways on the atomic scale. To quantify the influence of local barrier changes on the macroscopic transport of  $Mg^{2+}$  ions, we determined the minimal M-deficiency  $x$  in  $Mg_xM_{3-x}X_4$  required for percolation. Using a cut-off of 750 meV and

500 meV for cathodes and solid electrolytes, respectively, we found that the stoichiometric  $\text{MgMn}_2\text{O}_4$  and  $\text{MgIn}_2\text{S}_4$  compositions are Mg percolating up to  $\sim 55\text{--}59\%$  and  $44\%$  inversion. Since the degree of inversion in the spinels considered in this work may vary between  $20\%$  and  $85\%$  depending on the method of preparation,<sup>29,30,38</sup> a careful calibration of the synthesis conditions is essential to ensure sufficient Mg transport and to reduce the resultant impedance. In addition, spinel inversion can affect the electrochemical properties of cathode materials by changing the phase behavior, average voltage, and extractable capacities. Specifically, we find that the degree of inversion can change dynamically during electrochemical Mg cycling, as indicated by the 0 K phase diagram of the  $\text{Mg}_x\text{Mn}_2\text{O}_4$  system and the activation barriers for  $\text{Mn}^{2+}$  hopping. Notably, even low degrees of inversion ( $i < 0.4$ ) can detrimentally reduce the extractable capacity in stoichiometric  $\text{MgMn}_2\text{O}_4$ , with an estimated  $15\%$  decrease in capacity with every  $10\%$  increase in inversion. Thus, spinel inversion can hinder the electrochemical performance of both cathodes and solid electrolytes in MV systems and synthesis efforts must always be made to stabilize the normal spinel structure.

Given that the  $\text{Mg}^{2+}$  migration barriers over a range of oxide<sup>11</sup> and sulfide spinels<sup>12</sup> show similar trends, we ex-

pect similar behavior upon inversion in other spinel materials. Finally, the framework developed in this work, particularly the data reported on percolation thresholds and extractable Mg, is readily transferable to other spinels that have potential applications in Li-ion, Na-ion, Ca/Zn-multivalent and other battery fields.

### Acknowledgments

The current work is fully supported by the Joint Center for Energy Storage Research (JCESR), an Energy Innovation Hub funded by the U.S. Department of Energy, Office of Science and Basic Energy Sciences. This study was supported by Subcontract 3F-31144. The authors thank the National Energy Research Scientific Computing Center (NERSC) for providing computing resources. Use of the Advanced Photon Source at Argonne National Laboratory was supported by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences, under Contract No. DE-AC02-06CH11357. The authors declare no competing financial interests. GSG is thankful to Daniel C. Hannah at Lawrence Berkeley National Laboratory for a thorough reading of the manuscript.

\* Electronic address: gautam91@mit.edu

† G. S. Gautam and P. Canepa contributed equally to the work

‡ Electronic address: gceder@berkeley.edu, gceder@lbl.gov

<sup>1</sup> D. Aurbach, Z. Lu, A. Schechter, Y. Gofer, H. Gizbar, R. Turgeman, Y. Cohen, M. Moshkovich, and E. Levi, *Nature* **407**, 724 (2000), ISSN 0028-0836, URL <http://dx.doi.org/10.1038/35037553>.

<sup>2</sup> P. Canepa, G. S. Gautam, D. C. Hannah, R. Malik, M. Liu, K. G. Gallagher, K. A. Persson, and G. Ceder, *Chem. Rev.* (2017).

<sup>3</sup> H. D. Yoo, I. Shterenberg, Y. Gofer, G. Gershinsky, N. Pour, and D. Aurbach, *Energy Environ. Sci.* **6**, 2265 (2013), ISSN 1754-5706, URL <http://dx.doi.org/10.1039/C3EE40871J>.

<sup>4</sup> J. O. Besenhard and M. Winter, *ChemPhysChem* **3**, 155 (2002), ISSN 1439-7641, URL [http://dx.doi.org/10.1002/1439-7641\(20020215\)3:2<155::AID-CPHC155>3.0.CO;2-S](http://dx.doi.org/10.1002/1439-7641(20020215)3:2<155::AID-CPHC155>3.0.CO;2-S).

<sup>5</sup> J. Muldoon, C. B. Bucur, and T. D. Gregory, *Chem. Rev.* **114**, 11683 (2014), URL <http://dx.doi.org/10.1021/cr500049y>.

<sup>6</sup> P. Canepa, S. Jayaraman, L. Cheng, N. Rajput, W. D. Richards, G. Sai Gautam, L. A. Curtiss, K. Persson, and G. Ceder, *Energy Environ. Sci.* **8**, 3718 (2015), ISSN 1754-5706, URL <http://dx.doi.org/10.1039/C5EE02340H>.

<sup>7</sup> P. Canepa, G. S. Gautam, R. Malik, S. Jayaraman, Z. Rong, K. R. Zavadil, K. Persson, and G. Ceder, *Chem. Mater.* **27**, 3317 (2015), URL <http://dx.doi.org/10.1021/acs.chemmater.5b00389>.

<sup>8</sup> Z. Rong, R. Malik, P. Canepa, G. Sai Gautam, M. Liu, A. Jain, K. Persson, and G. Ceder, *Chem. Mater.* **27**,

6016 (2015), ISSN 1520-5002, URL <http://dx.doi.org/10.1021/acs.chemmater.5b02342>.

<sup>9</sup> I. Brown, *Acta Crystallogr. Sect. B* **44**, 545 (1988), URL <http://dx.doi.org/10.1107/S0108768188007712>.

<sup>10</sup> G. Sai Gautam, P. Canepa, R. Malik, M. Liu, K. Persson, and G. Ceder, *Chem. Commun.* **51**, 13619 (2015), ISSN 1364-548X, URL <http://dx.doi.org/10.1039/C5CC04947D>.

<sup>11</sup> M. Liu, Z. Rong, R. Malik, P. Canepa, A. Jain, G. Ceder, and K. A. Persson, *Energy Environ. Sci.* **8**, 964 (2015), ISSN 1754-5706, URL <http://dx.doi.org/10.1039/C4EE03389B>.

<sup>12</sup> M. Liu, A. Jain, Z. Rong, X. Qu, P. Canepa, R. Malik, G. Ceder, and K. Persson, *Energy Environ. Sci.* **9**, 3201 (2016), URL <http://dx.doi.org/10.1039/C6EE01731B>.

<sup>13</sup> M. S. Whittingham, *Chem. Rev.* **104**, 4271 (2004), ISSN 1520-6890, URL <http://dx.doi.org/10.1021/cr020731c>.

<sup>14</sup> M. Thackeray, P. Johnson, L. de Picciotto, P. Bruce, and J. Goodenough, *Mater. Res. Bull.* **19**, 179 (1984), ISSN 0025-5408, URL [http://dx.doi.org/10.1016/0025-5408\(84\)90088-6](http://dx.doi.org/10.1016/0025-5408(84)90088-6).

<sup>15</sup> M. Wagemaker, A. Van Der Ven, D. Morgan, G. Ceder, F. Mulder, and G. Kearley, *Chemical Physics* **317**, 130 (2005).

<sup>16</sup> J. Reed, G. Ceder, and A. V. D. Ven, *Electrochem. Solid-State Lett.* **4**, A78 (2001), URL <http://dx.doi.org/10.1149/1.1368896>.

<sup>17</sup> A. Van der Ven, C. Marianetti, D. Morgan, and G. Ceder, *Solid State Ionics* **135**, 21 (2000).

<sup>18</sup> E. Ferg, R. Gummow, A. De Kock, and M. Thackeray, *J. Electrochem. Soc.* **141**, L147 (1994).

- <sup>19</sup> D. Andre, S.-J. Kim, P. Lamp, S. F. Lux, F. Maglia, O. Paschos, and B. Stiaszny, *J. Mater. Chem. A* **3**, 6709 (2015), ISSN 2050-7496, URL <http://dx.doi.org/10.1039/C5TA00361J>.
- <sup>20</sup> G. Gershinsky, H. D. Yoo, Y. Gofer, and D. Aurbach, *Langmuir* **29**, 10964 (2013), ISSN 1520-5827, URL <http://dx.doi.org/10.1021/la402391f>.
- <sup>21</sup> G. Sai Gautam, P. Canepa, A. Abdellahi, A. Urban, R. Malik, and G. Ceder, *Chem. Mater.* **27**, 3733 (2015), ISSN 1520-5002, URL <http://dx.doi.org/10.1021/acs.chemmater.5b00957>.
- <sup>22</sup> G. Sai Gautam, P. Canepa, W. D. Richards, R. Malik, and G. Ceder, *Nano Lett.* **16**, 2426 (2016), URL <http://dx.doi.org/10.1021/acs.nanolett.5b05273>.
- <sup>23</sup> N. Sa, T. L. Kinnibrugh, H. Wang, G. S. Gautam, K. W. Chapman, J. T. Vaughey, B. Key, T. T. Fister, J. W. Freeland, D. L. Proffit, et al., *Chem. Mater.* **28**, 2962 (2016), URL <http://dx.doi.org/10.1021/acs.chemmater.6b00026>.
- <sup>24</sup> S. Tepavcevic, Y. Liu, D. Zhou, B. Lai, J. Maser, X. Zuo, H. Chan, P. Král, C. S. Johnson, V. Stamenkovic, et al., *ACS Nano* **9**, 8194 (2015), ISSN 1936-086X, URL <http://dx.doi.org/10.1021/acsnano.5b02450>.
- <sup>25</sup> P. Novák, V. Shklover, and R. Nesper, *Z. Phys. Chem.* **185**, 51 (1994), URL [http://dx.doi.org/10.1524/zpch.1994.185.Part\\_1.051](http://dx.doi.org/10.1524/zpch.1994.185.Part_1.051).
- <sup>26</sup> C. Kim, P. J. Phillips, B. Key, T. Yi, D. Nordlund, Y.-S. Yu, R. D. Bayliss, S.-D. Han, M. He, Z. Zhang, et al., *Adv. Mater.* **27**, 3377 (2015), ISSN 0935-9648, URL <http://dx.doi.org/10.1002/adma.201500083>.
- <sup>27</sup> Z. Feng, X. Chen, L. Qiao, A. L. Lipson, T. T. Fister, L. Zeng, C. Kim, T. Yi, N. Sa, D. L. Proffit, et al., *ACS Appl. Mater. Interfaces* **7**, 28438 (2015), URL <http://dx.doi.org/10.1021/acssami.5b09346>.
- <sup>28</sup> S. Kim, K. W. Nam, S. Lee, W. Cho, J.-S. Kim, B. G. Kim, Y. Oshima, J.-S. Kim, S.-G. Doo, H. Chang, et al., *Angew. Chem. Int. Ed.* **54**, 15094 (2015), ISSN 1433-7851, URL <http://dx.doi.org/10.1002/anie.201505487>.
- <sup>29</sup> K. Irani, A. Sinha, and A. Biswas, *J. Phys. Chem. Solids* **23**, 711 (1962), URL [http://dx.doi.org/10.1016/0022-3697\(62\)90530-9](http://dx.doi.org/10.1016/0022-3697(62)90530-9).
- <sup>30</sup> L. Malavasi, P. Ghigna, G. Chiodelli, G. Maggi, and G. Flor, *J. Solid State Chem.* **166**, 171 (2002), ISSN 0022-4596, URL <http://dx.doi.org/10.1006/jssc.2002.9577>.
- <sup>31</sup> M. Rosenberg and P. Nicolau, *Phys. Stat. Sol.* **6**, 101 (1964).
- <sup>32</sup> R. Mănăilă and P. Păușescu, *Phys. Stat. Sol.* **9**, 385 (1965).
- <sup>33</sup> N. Radhakrishnan and A. Biswas, *Phys. Stat. Sol. (a)* **37**, 719 (1976).
- <sup>34</sup> J. Reed and G. Ceder, *Chem Rev* **104**, 4513 (2004).
- <sup>35</sup> J. Lee, A. Urban, X. Li, D. Su, G. Hautier, and G. Ceder, *Science* **343**, 519 (2014).
- <sup>36</sup> A. Urban, J. Lee, and G. Ceder, *Adv. Energy Mater.* **4**, 1400478 (2014).
- <sup>37</sup> Y. Seminovski, P. Palacios, P. Wahnón, and R. Grau-Crespo, *Appl. Phys. Lett.* **100**, 102112 (2012).
- <sup>38</sup> P. Canepa, S.-H. Bo, G. S. Gautam, B. Key, W. D. Richards, Y. Wang, J. Li, and G. Ceder, under review (2017).
- <sup>39</sup> H. Hahn and W. Klingler, *Z. Anorg. Allg. Chem.* **263**, 177 (1950).
- <sup>40</sup> M. Wakaki, O. Shintani, T. Ogawa, and T. Arai, *Jpn. J. Appl. Phys.* **19**, 255 (1980).
- <sup>41</sup> J. C. Bachman, S. Muy, A. Grimaud, H.-H. Chang, N. Pour, S. F. Lux, O. Paschos, F. Maglia, S. Lupart, P. Lamp, et al., *Chem. Rev.* **116**, 140 (2016), URL <http://dx.doi.org/10.1021/acs.chemrev.5b00563>.
- <sup>42</sup> A. Walsh, S.-H. Wei, Y. Yan, M. Al-Jassim, J. A. Turner, M. Woodhouse, and B. Parkinson, *Phys. Rev. B* **76**, 165119 (2007).
- <sup>43</sup> D. Das and S. Ghosh, *J. Phys.: Condens. Matter* **29**, 055805 (2016).
- <sup>44</sup> L. Schwarz, Z. Galazka, T. M. Gesing, and D. Klimm, *Cryst. Res. Technol.* **50**, 961 (2015).
- <sup>45</sup> D. Santos-Carballal, A. Roldan, R. Grau-Crespo, and N. H. de Leeuw, *Phys. Rev. B* **91**, 195106 (2015).
- <sup>46</sup> B. Xu and S. Meng, *J. Power Sources* **195**, 4971 (2010).
- <sup>47</sup> G. S. Gautam, X. Sun, V. Duffort, L. F. Nazar, and G. Ceder, *J. Mater. Chem. A* **4**, 17643 (2016), URL <http://dx.doi.org/10.1039/C6TA07804D>.
- <sup>48</sup> K. E. Sickafus, J. M. Wills, and N. W. Grimes, *J. Am. Ceram. Soc.* **82**, 3279 (1999).
- <sup>49</sup> L. Pauling, *The nature of the chemical bond and the structure of molecules and crystals: an introduction to modern structural chemistry*, vol. 18 (Cornell university press, 1960).
- <sup>50</sup> P. P. Ewald, *Ann. Phys.* **369**, 253 (1921).
- <sup>51</sup> D. Stauffer and A. Aharony, *Introduction to percolation theory* (CRC press, 1994).
- <sup>52</sup> A. Hunt and R. Ewing, *Percolation theory for flow in porous media (Lecture Notes in Physics 674)* (Soil Sci Soc America, 2006).
- <sup>53</sup> M. B. Isichenko, *Rev Mod Phys* **64**, 961 (1992).
- <sup>54</sup> J. W. Essam, *Rep. Prog. Phys.* **43**, 833 (1980).
- <sup>55</sup> S. C. Van der Marck, *Int J Mod Phys C* **9**, 529 (1998).
- <sup>56</sup> C. D. Lorenz and R. M. Ziff, *Phys Rev E* **57**, 230 (1998).
- <sup>57</sup> A. Urban, D.-H. Seo, and G. Ceder, *npj Comput. Mater.* **2**, 16002 (2016), URL <http://dx.doi.org/10.1038/npjcompumats.2016.2>.
- <sup>58</sup> P. Hohenberg and W. Kohn, *Phys Rev* **136**, B864 (1964).
- <sup>59</sup> W. Kohn and L. J. Sham, *Phys Rev* **140**, A1133 (1965).
- <sup>60</sup> A. Jain, Y. Shin, and K. A. Persson, *Nature Reviews Materials* **1**, 15004 (2016).
- <sup>61</sup> G. Kresse and J. Hafner, *Phys. Rev. B* **47**, 558 (1993).
- <sup>62</sup> G. Kresse and J. Furthmüller, *Phys Rev B* **54**, 11169 (1996).
- <sup>63</sup> G. Kresse and D. Joubert, *Phys. Rev. B* **59**, 1758 (1999).
- <sup>64</sup> J. P. Perdew, K. Burke, and M. Ernzerhof, *Phys Rev Lett* **77**, 3865 (1996).
- <sup>65</sup> N. Sanjana, A. Biswas, and A. Sinha, *J. Sci. Ind. Res. B* **19**, 415 (1960).
- <sup>66</sup> J. P. Perdew, A. Ruzsinszky, G. I. Csonka, O. A. Vydrov, G. E. Scuseria, L. A. Constantin, X. Zhou, and K. Burke, *Phys. Rev. Lett.* **100**, 136406 (2008).
- <sup>67</sup> D. A. Kitchaev, H. Peng, Y. Liu, J. Sun, J. P. Perdew, and G. Ceder, *Phys. Rev. B* **93**, 045132 (2016), URL <http://dx.doi.org/10.1103/PhysRevB.93.045132>.
- <sup>68</sup> V. I. Anisimov, J. Zaanen, and O. K. Andersen, *Phys. Rev. B* **44**, 943 (1991).
- <sup>69</sup> F. Zhou, M. Cococcioni, C. A. Marianetti, D. Morgan, and G. Ceder, *Physical Review B* **70**, 235121 (2004), URL <http://dx.doi.org/10.1103/PhysRevB.70.235121>.
- <sup>70</sup> A. Jain, G. Hautier, S. P. Ong, C. J. Moore, C. C. Fischer, K. A. Persson, and G. Ceder, *Phys. Rev. B* **84**, 045115 (2011).
- <sup>71</sup> G. Henkelman and H. Jónsson, *J. Chem. Phys.* **113**, 9978 (2000).

- <sup>72</sup> D. Sheppard, R. Terrell, and G. Henkelman, *J. Chem. Phys.* **128**, 134106 (2008).
- <sup>73</sup> M. Newman and R. Ziff, *Phys. Rev. Lett.* **85**, 4104 (2000).
- <sup>74</sup> X. Sun, V. Duffort, P. Bonnicksen, Z. Rong, M. Liu, K. Persson, G. Ceder, and L. F. Nazar, *Energy Environ. Sci.* **9**, 2273 (2016), URL <http://dx.doi.org/10.1039/C6EE00724D>.
- <sup>75</sup> C. Ling, R. Zhang, and F. Mizuno, *ACS Appl. Mater. Interfaces* **8**, 4508 (2016).
- <sup>76</sup> Y. Wang, W. D. Richards, S. P. Ong, L. J. Miara, J. C. Kim, Y. Mo, and G. Ceder, *Nat. Mater.* **14**, 1026 (2015), URL <http://dx.doi.org/10.1038/nmat4369>.
- <sup>77</sup> M. K. Aydinol, A. F. Kohan, G. Ceder, K. Cho, and J. Joannopoulos, *Phys. Rev. B* **56**, 1354 (1997), URL <http://dx.doi.org/10.1103/PhysRevB.56.1354>.
- <sup>78</sup> A. Jain, S. P. Ong, G. Hautier, W. Chen, W. D. Richards, S. Dacek, S. Cholia, D. Gunter, D. Skinner, G. Ceder, et al., *APL Materials* **1**, 011002 (2013), ISSN 2166532X, URL <http://link.aip.org/link/AMPADS/v1/i1/p011002/s1&Agg=doi>.
- <sup>79</sup> S. Bağcı, H. Tütüncü, S. Duman, E. Bulut, M. Özacar, and G. Srivastava, *J. Phys. Chem. Solids* **75**, 463 (2014).
- <sup>80</sup> C. Ling and F. Mizuno, *Chem. Mater.* **25**, 3062 (2013), ISSN 1520-5002, URL <http://dx.doi.org/10.1021/cm401250c>.
- <sup>81</sup> X. Sun, V. Duffort, B. L. Mehdi, N. D. Browning, and L. F. Nazar, *Chem. Mater.* **28**, 534 (2016), ISSN 1520-5002, URL <http://dx.doi.org/10.1021/acs.chemmater.5b03983>.